

Reverse Engineering a passive UHF RFID Tag

Why not?

Brian Degnan, Ph.D.

Acknowledgements



- Dr. Ed Reiter
- Dr. Greg Schultz



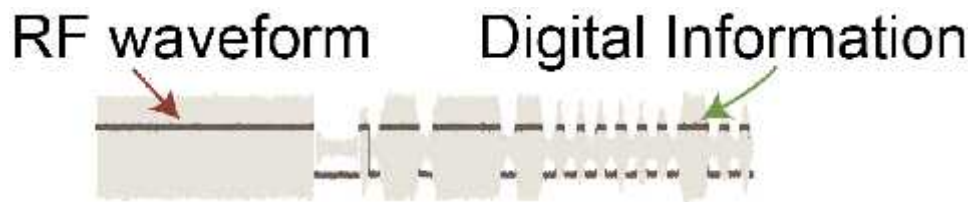
- Prof. Greg Durgin
- Prof. Jennifer Hasler



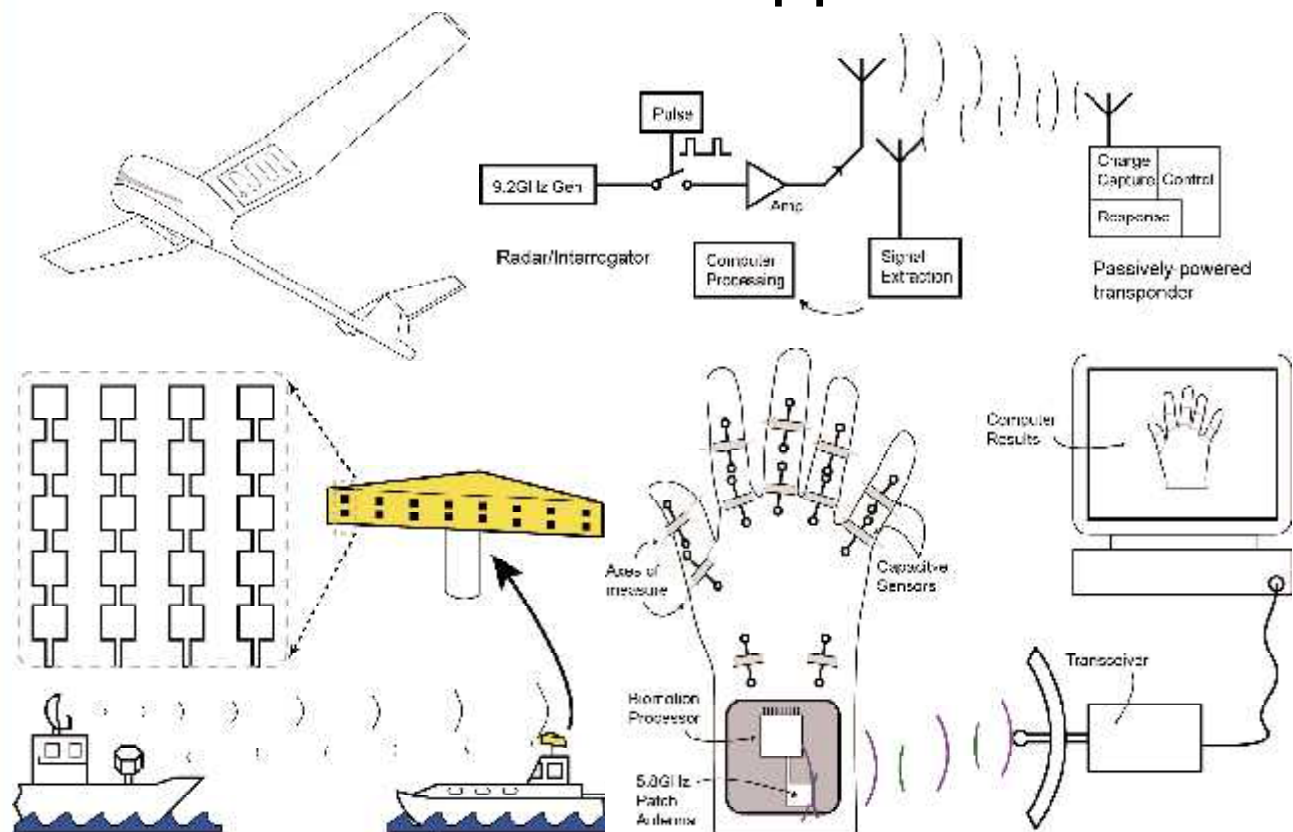
- The SIMON team
- Oakridge Nat. Lab

What's this about?

- Some circuits for Gen2v2 for UHF RFID
- Why the electronic side is relevant.
- Components (same but different)
- System components and bounding the problem
- System intuition

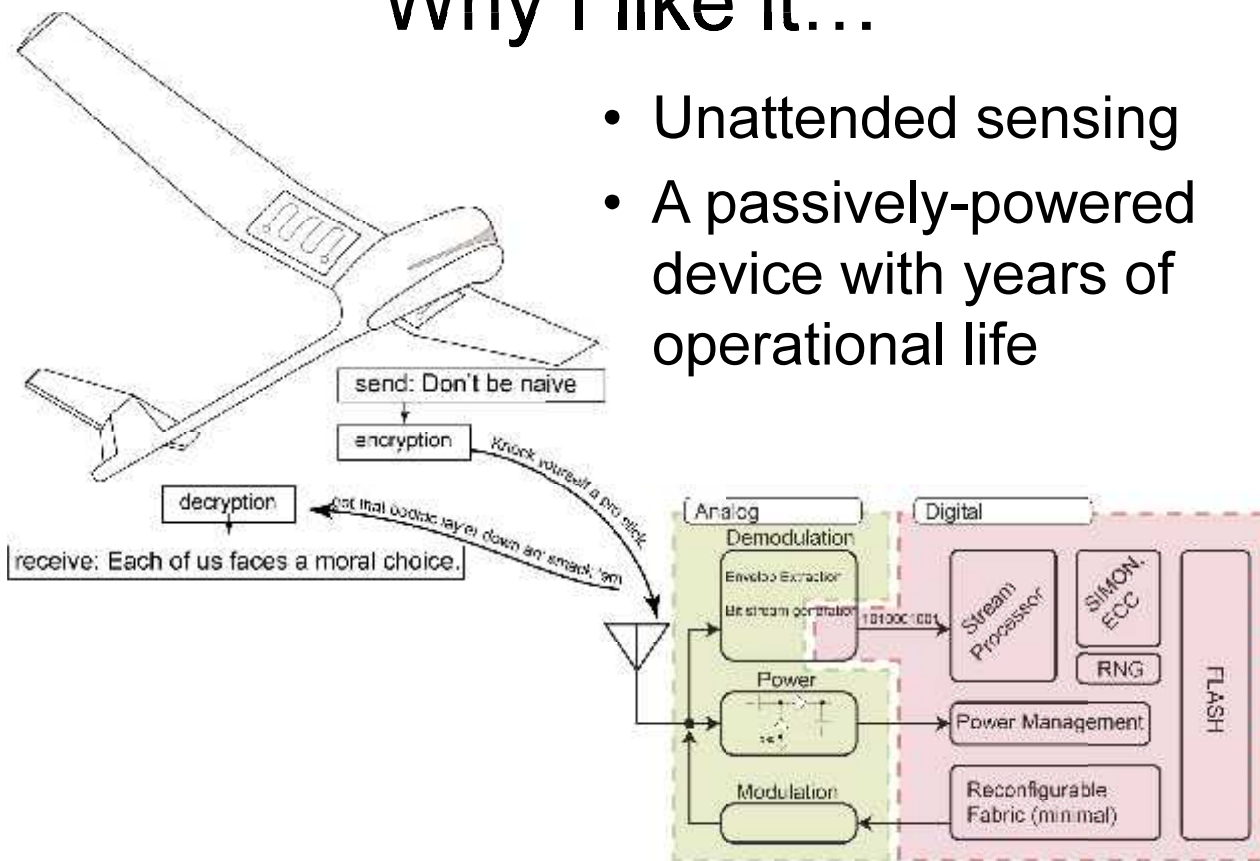


RFID Processor Applications

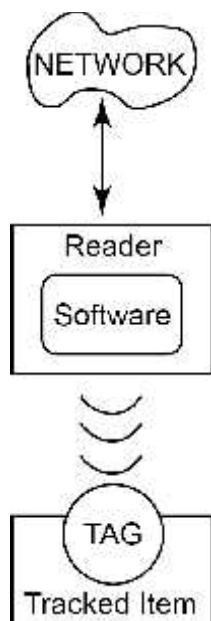


Why I like it...

- Unattended sensing
- A passively-powered device with years of operational life



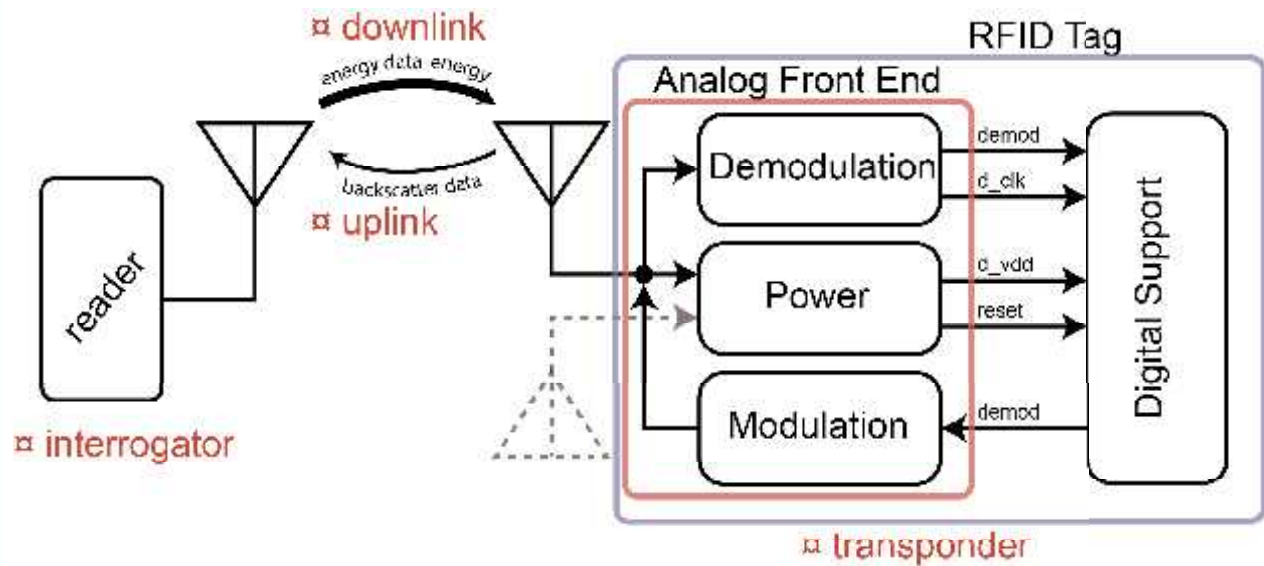
System Overview, in Context



- Tags communicate wirelessly
- Tag memory identifies individual items (TID, EPC, more)
- Small amount of memory
- Applications read/write small amounts of data

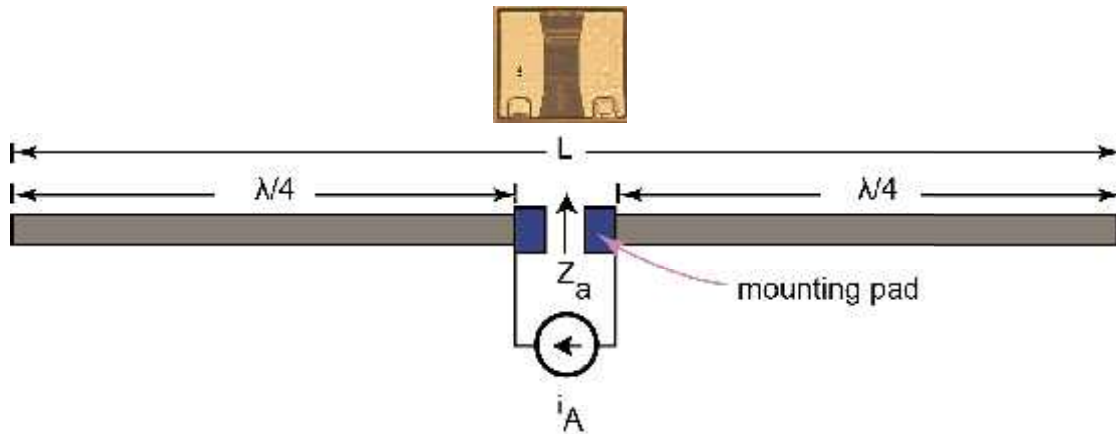


The RFID System



- Gen2: 860MHz-960MHz +/- 40kHz-640kHz
- Passively Powered

“Antenna Powered”



Wireless, Tag System Datalink

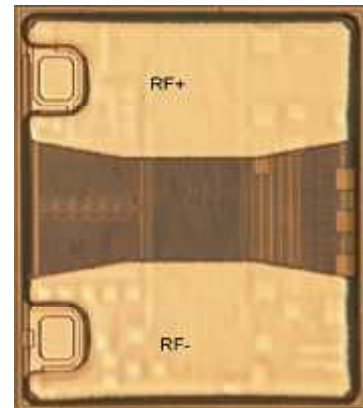
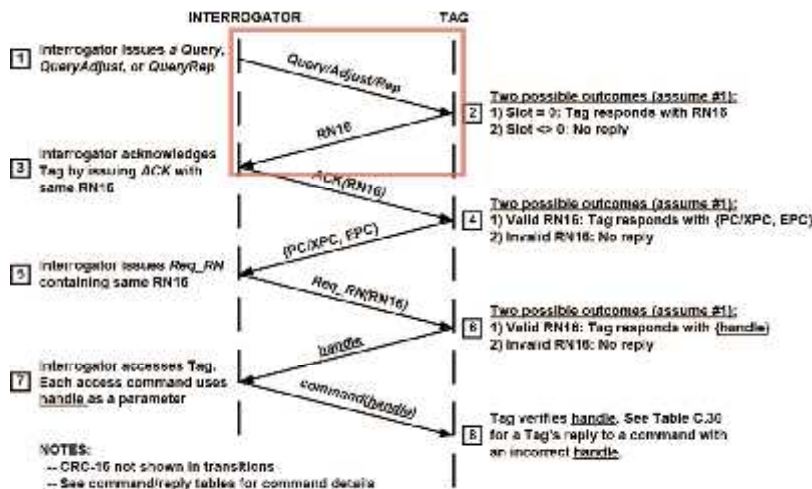
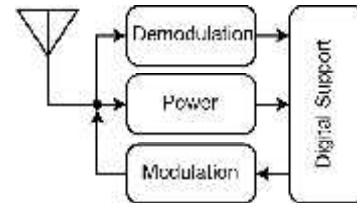
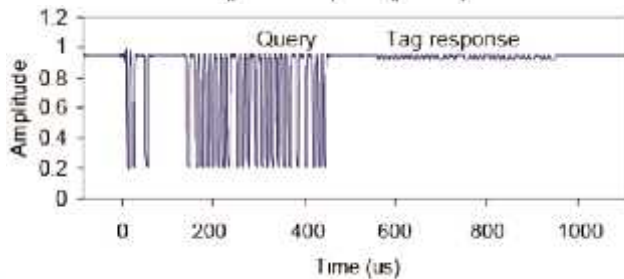
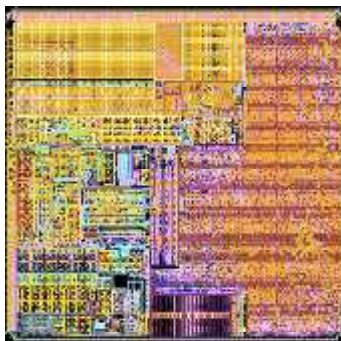
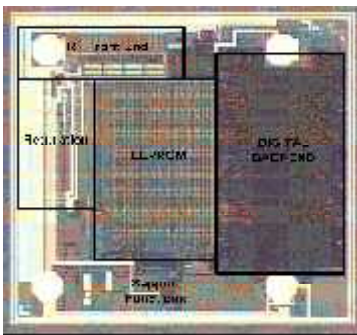


Figure E.1: Example of Tag Inventory and access



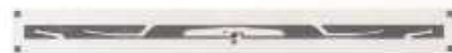
Economics of semiconductors



- About USD\$ 0.05 per 1mm² (can be cheaper)
- Physically limited by the size of “sand”
- They must be attached to an antenna

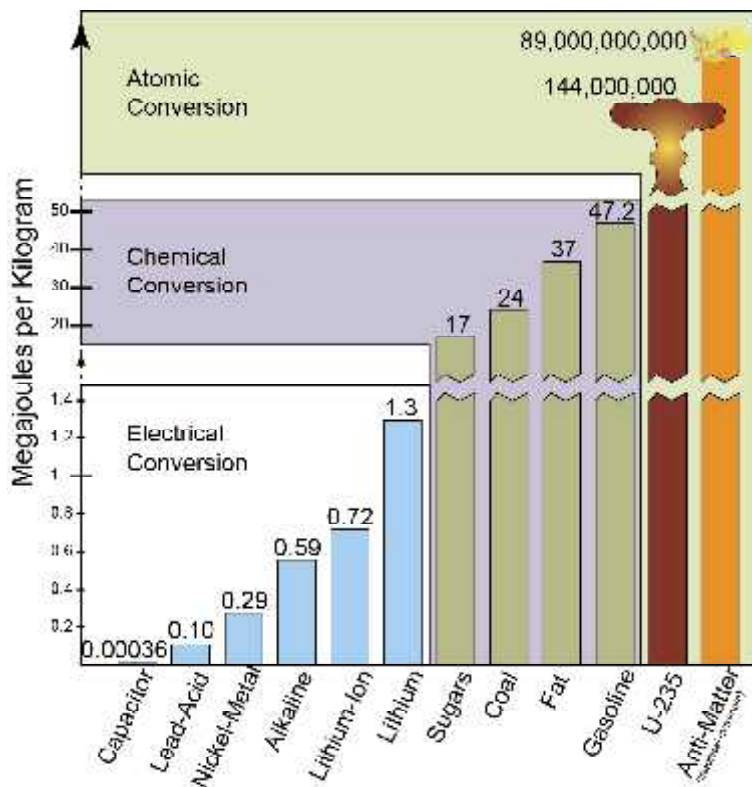


Satellite(37mmX22mm)

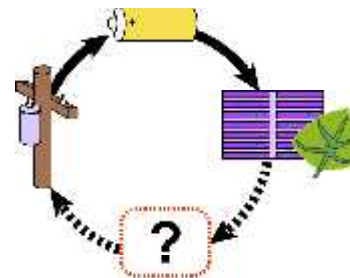


Linear(100mmX10mm)

Energy Storage



- 1000J ~ 1m² sunlight second second
- 100J released from a human per second
- USA uses 4W EIRP



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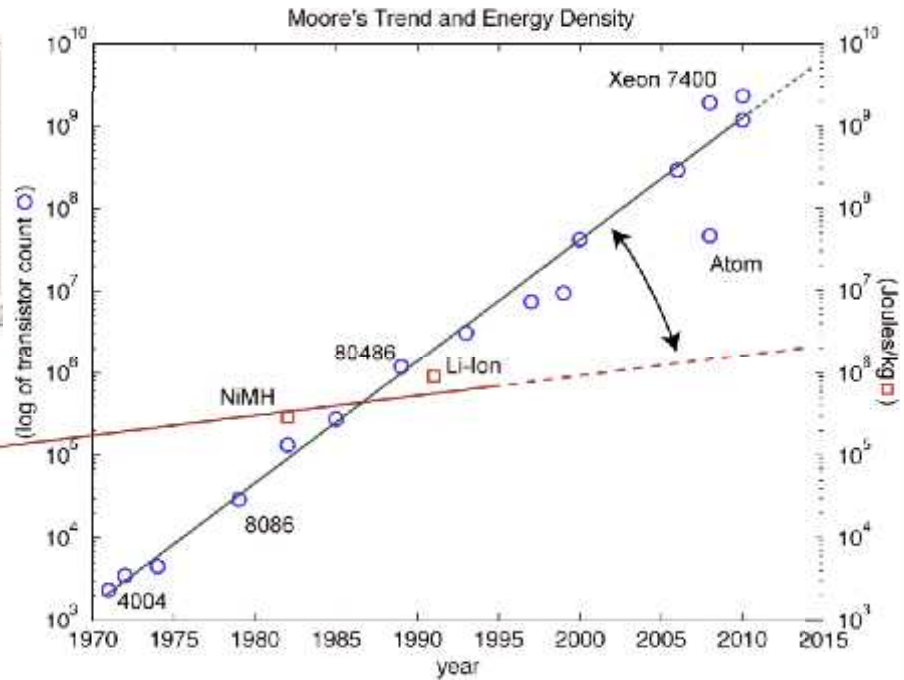
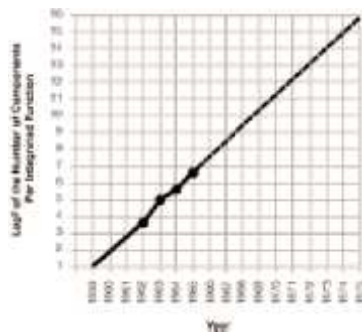
Components: Device Review

- MOSFET is one of many devices.
- Voltage controlled current source
- The input looks like a capacitor
- Multiple operating regimes
- Mathematics and physics are simple, but reality is terrible.

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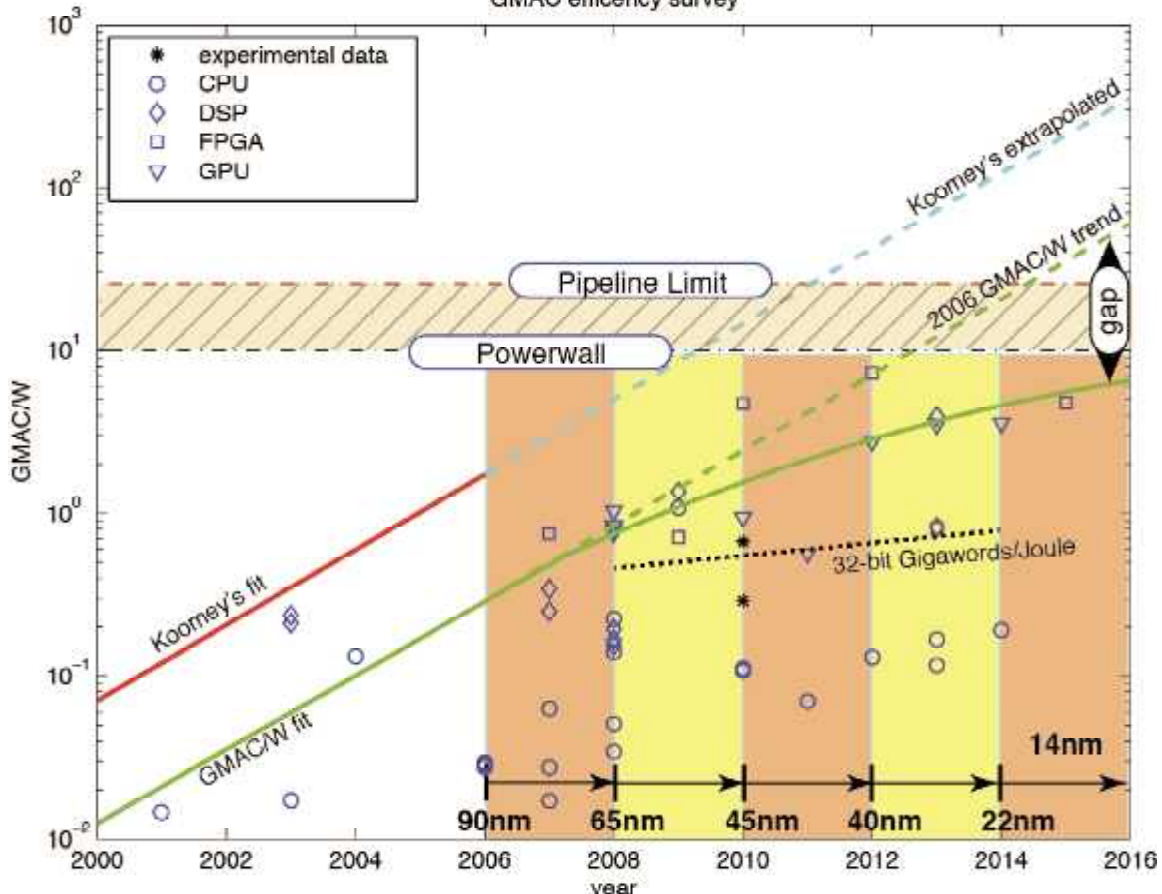
Moore More, Moore Less

Moore's original graph.

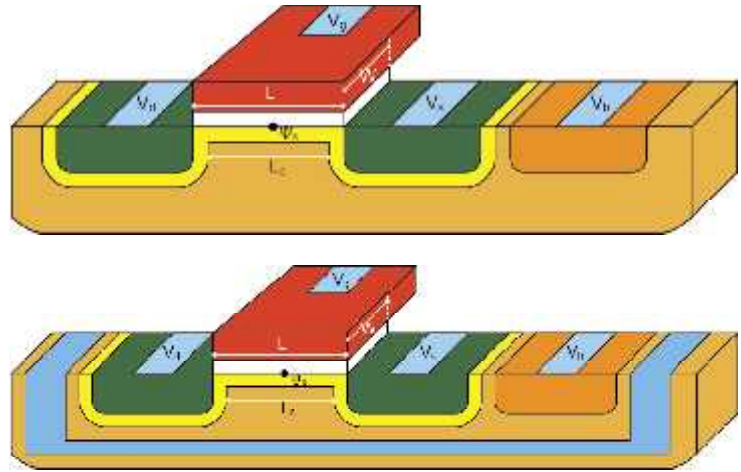
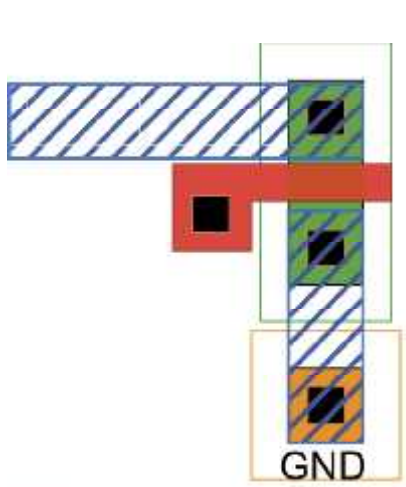


Assumptions:
 --Transistors scaling
 --Processing power correlates to transistors

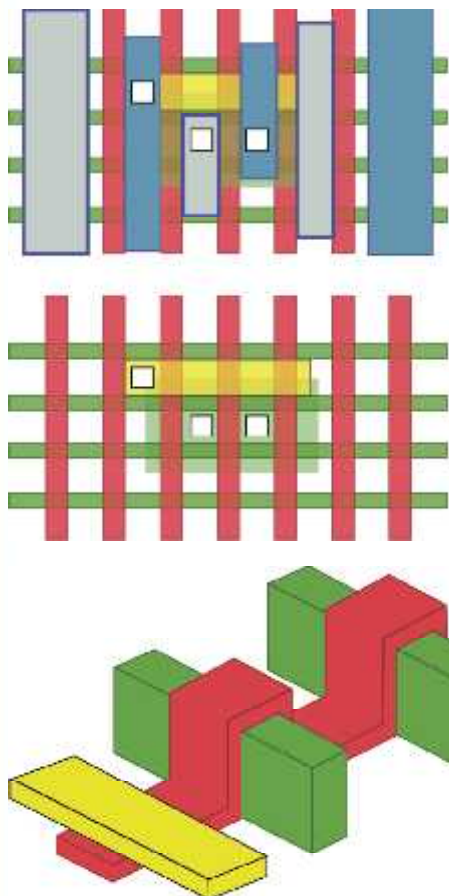
GMAC efficiency survey



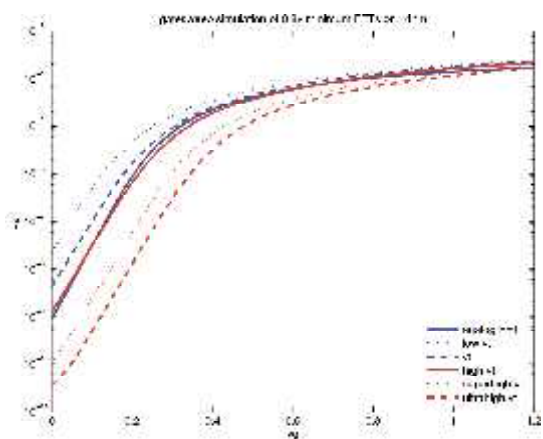
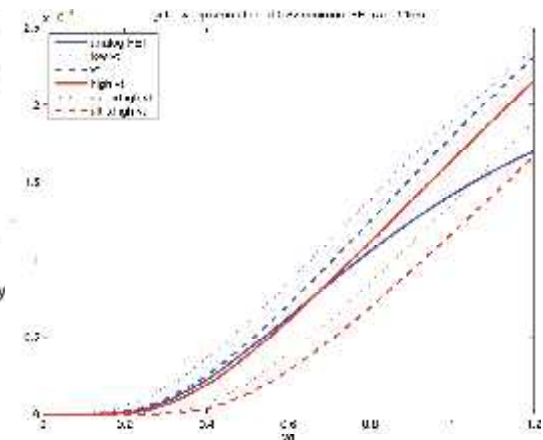
Transistors: how things used to be.



- contact
- metal 1
- poly
- n-active
- p-active



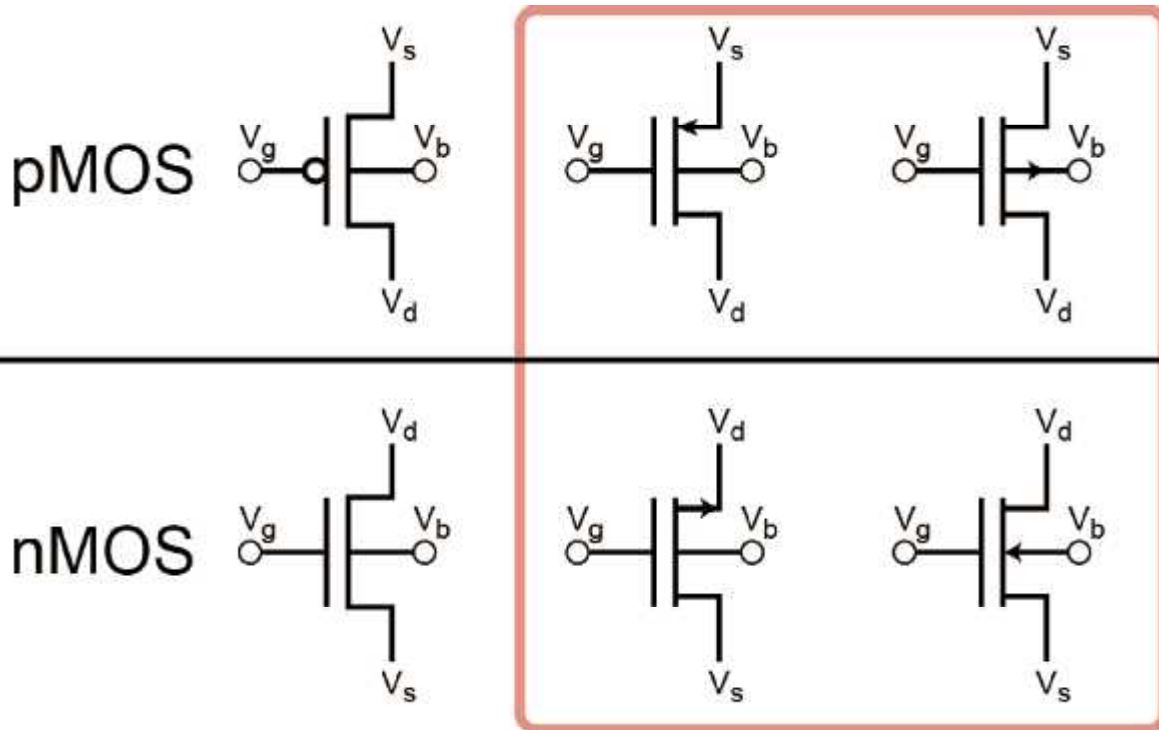
- Metal 1C0
- Metal 1C1
- contact
- n implant
- fin
- polysilicon
- contact poly



A 130nm Process, and Parts Review

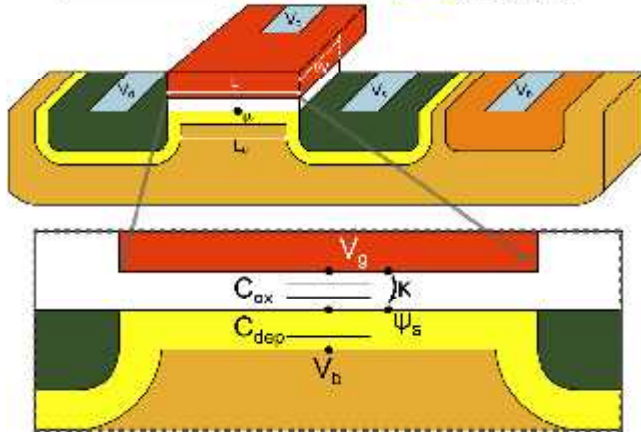
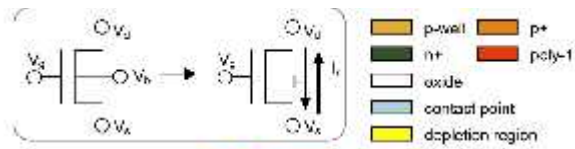
	Transistors			
	thin oxide		thick oxide	
	nFET	pFET	nFET	pFET
V_{DD}	1.2V	1.2V	2.4V	2.4V
L_{min}	120nm	120nm	240nm	240nm
V_{th}	0.30V	-0.35V	0.4V	-0.45V
I_{off}	300pA/ μm	200pA/ μm	10pA/ μm	10pA/ μm
I_{Dsat}	530mA/ μm	210mA/ μm	660mA/ μm	260mA/ μm
t_{ox}	2.2nm	2.2nm	5.2nm	5.2nm
	Capacitors			
	thin oxide		thick oxide	
	1.35fF/ μm^2			
MIM	1.35fF/ μm^2			
MOS	11fF/ μm^2	9fF/ μm^2	5.5fF/ μm^2	4.5fF/ μm^2

Transistor Symbols



Compact EKV Model

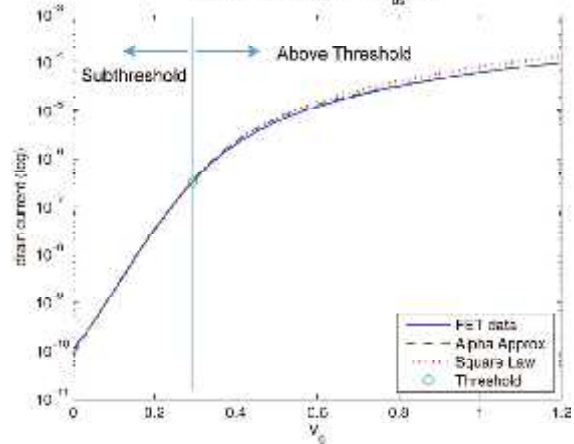
$$I_{f,r} = \frac{W}{L} 2U_T^2 \frac{\mu C_{ox}}{2\kappa} \ln^2 \left(1 + e^{\frac{\kappa(V_g - V_{T0}) + (1-\kappa)V_b - V_s + \sigma V_d}{2U_T}} \right)$$



$$I = I_f - I_r$$

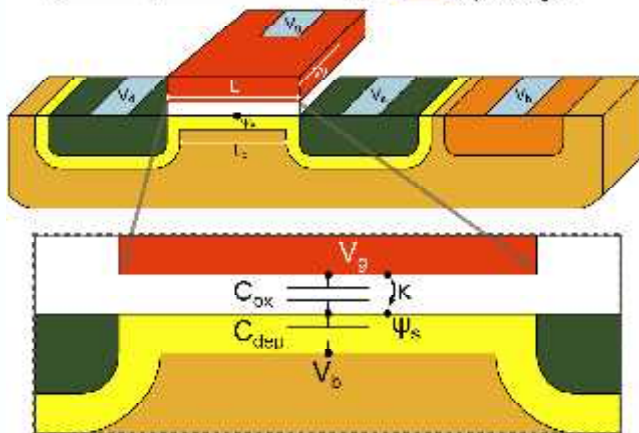
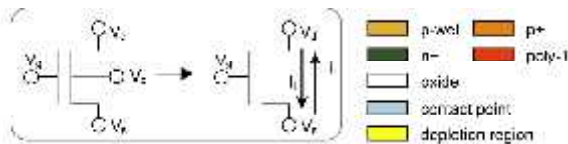
$$\kappa = \frac{C_{ox}}{C_{ox} + C_{dep}}$$

Gate sweep and models for $V_{ds} = 1.2$

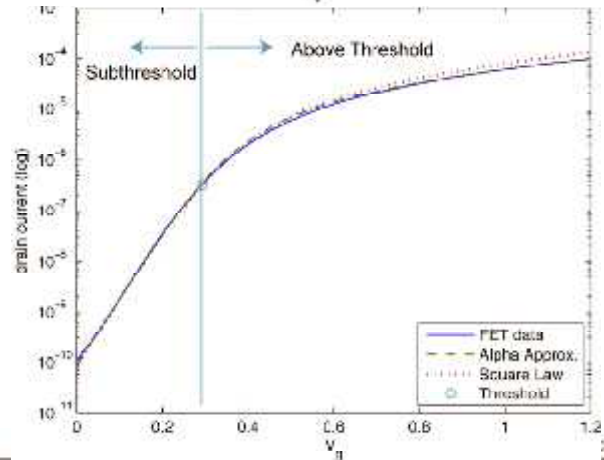
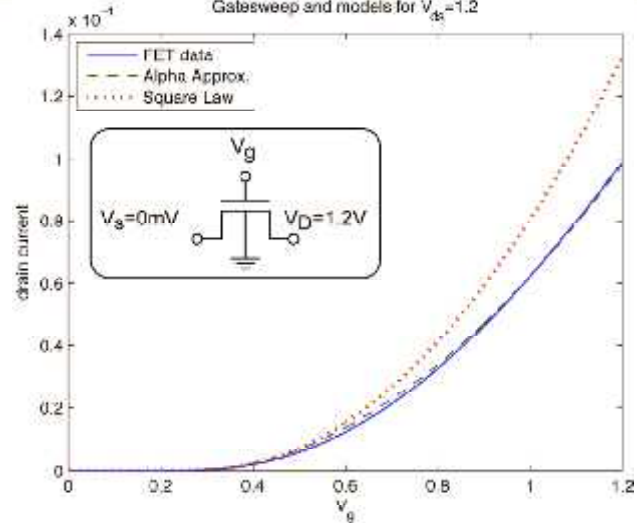


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nFET@130nm



Gate sweep and models for $V_{ds} = 1.2$



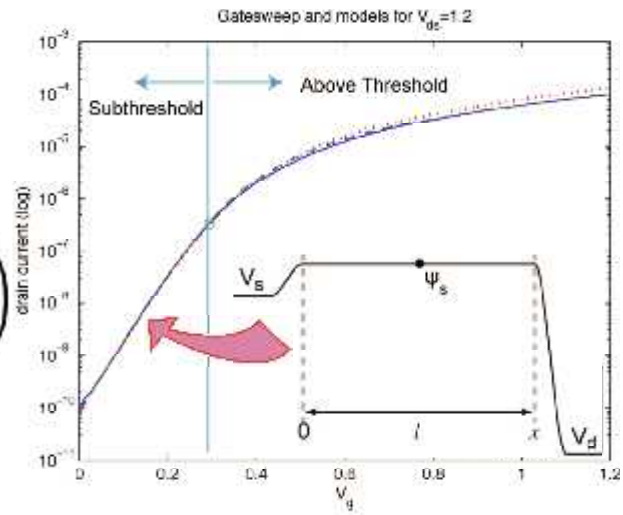
com

• Sub Vth

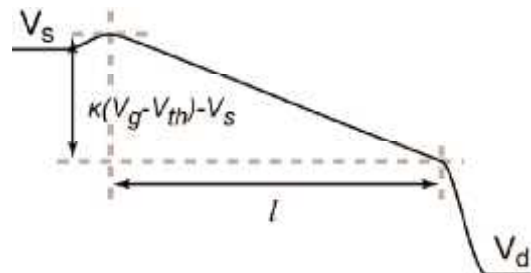
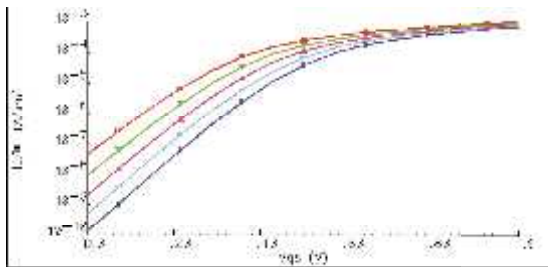
$$I = \frac{W}{L} \frac{2U_T^2 \mu C_{cox} e^{-\frac{\kappa V_{T0}}{U_T}}}{2\kappa} \left(e^{\frac{\kappa V_g - V_s}{U_T}} - e^{\frac{\kappa V_g - \sigma V_d}{U_T}} \right)$$

Node (nm)	Sub Vth%
500	12.8
350	12.4
250	24.4
180	34.4
130	35.3
90	35.0
65	40.0

V_{T0} nMOS threshold voltage
 Sub Vth% = range of diffusion operation



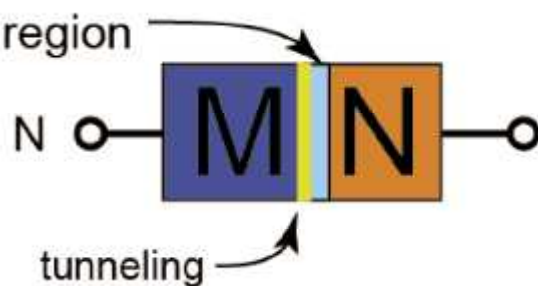
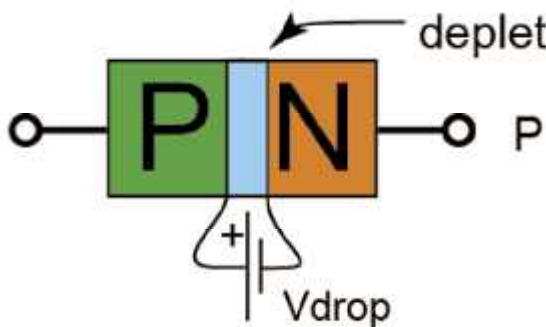
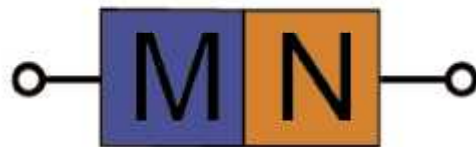
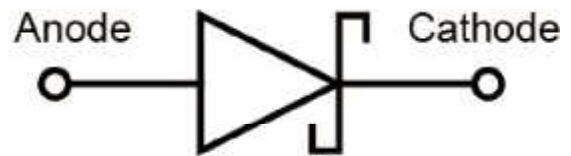
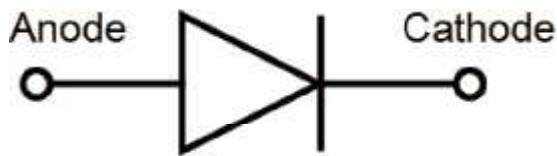
• Above Vth



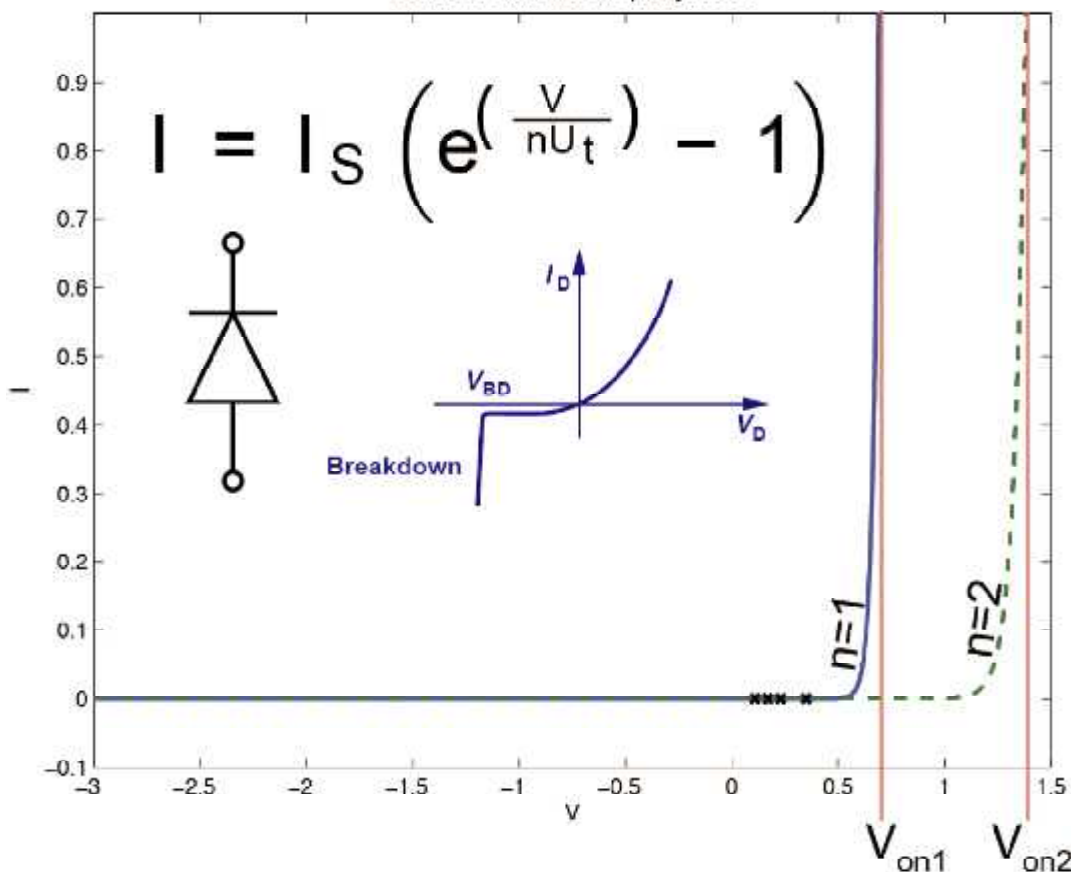
$$I = \frac{W}{L} U_T^2 \frac{\mu C_{cox}}{2\kappa} \left[(\kappa(V_g - \kappa V_{T0}) - V_s)^2 - (\kappa(V_g - \kappa V_{T0}) - \sigma V_d)^2 \right]$$

Graph: 65nm nFET gate sweep from IBM's 65nm advertisements.

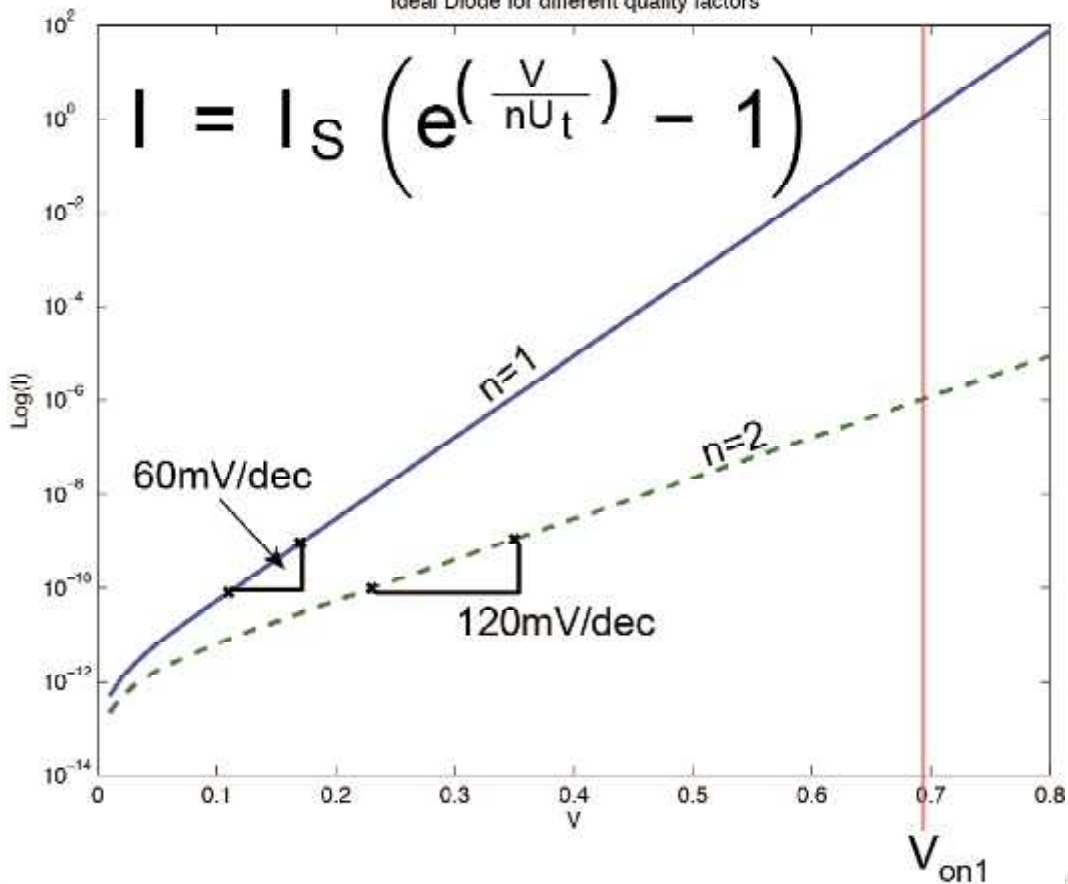
Diodes



Ideal Diode for different quality factors

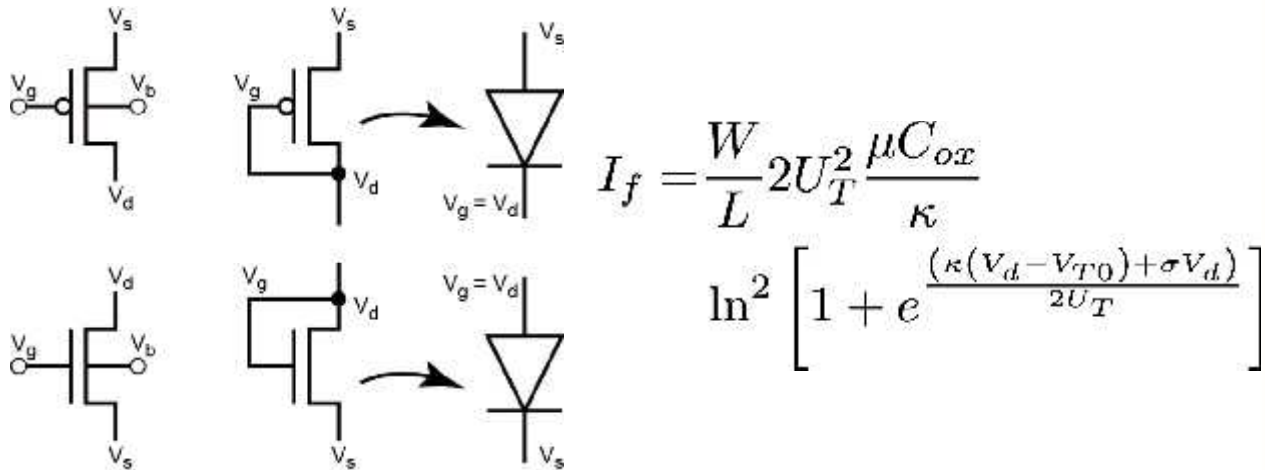


Ideal Diode for different quality factors

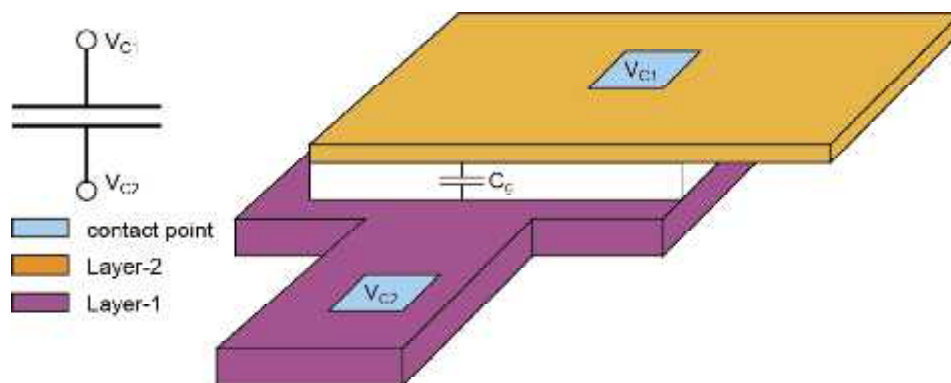


Diode Connected MOSFET

$$I_{f,r} = \frac{W}{L} 2U_T^2 \frac{\mu C_{ox}}{\kappa} \ln^2 \left[1 + e^{\frac{(\kappa(V_g - V_{T0}) + (1-\kappa)V_b - V_s + \sigma V_d)}{2U_T}} \right]$$

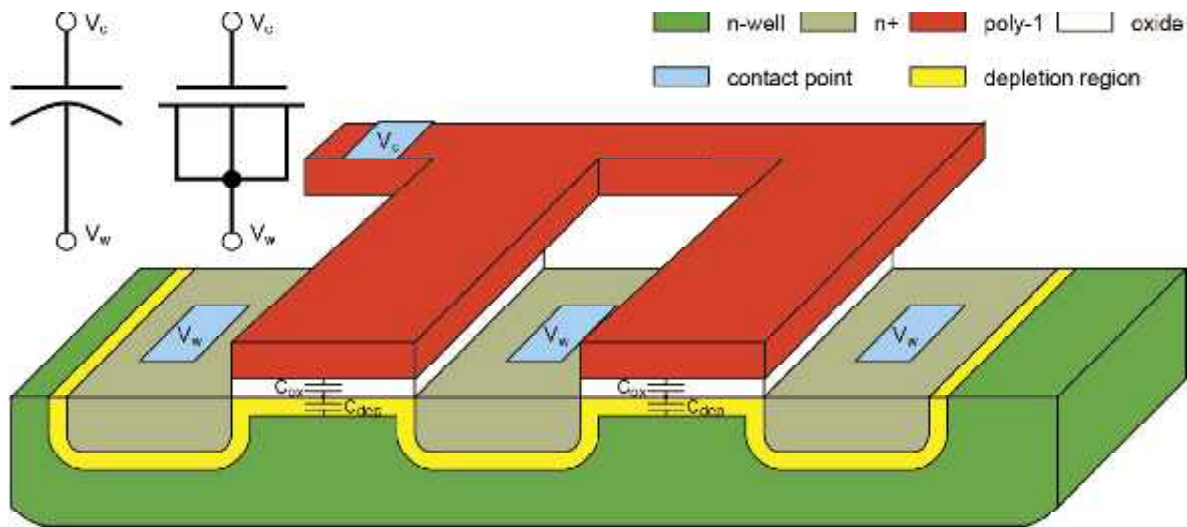


Linear Capacitor



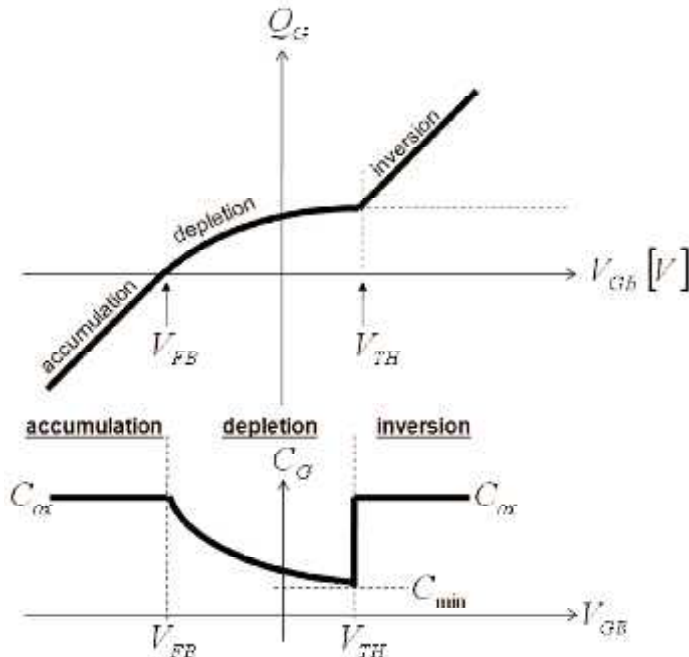
- Linearity is excellent
- Frequency response is excellent
- Charge Density is Low

Depletion Capacitor



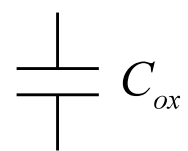
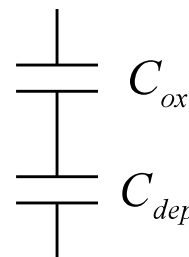
- Linearity is variable
- Frequency response is variable
- Charge Density is excellent

(n)MOS C-V curve



Depletion

Inversion

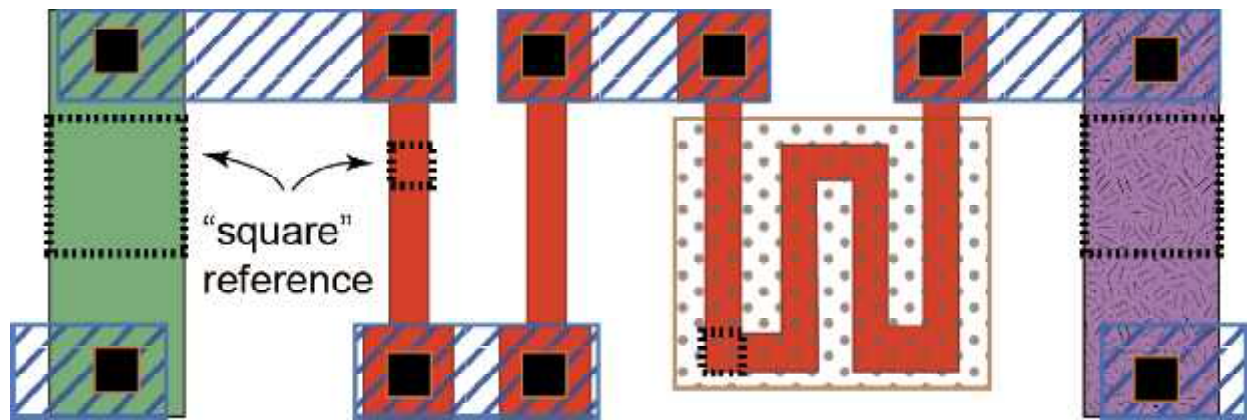


$$C_{\min} = \frac{C_{ox} C_{dep,\min}}{C_{ox} + C_{dep,\min}}$$

where $C_{dep,\min} \equiv \frac{\epsilon_{Si}}{X_{d,\max}}$

$$C_{dep} \equiv \frac{\epsilon_{Si}}{X_d} \quad C_{ox} \equiv \frac{\epsilon_{ox}}{t_{ox}}$$

Resistors			cost
n+ diffusion	75Ω/□	± 15%	included
p+ polysilicon	350Ω/□	± 20%	included
p- polysilicon	1500Ω/□	± 25%	extra
tantalum nitride	50Ω/□	± 5%	extra



System Punch List

- Harvest Energy (carrier wave supplied)
- Create a stable power supply (use the energy)
- Reset the System (ready the system)
- Decode the incoming data stream (extract)
- Respond to the decoded data (return)

Gen2 Protocol

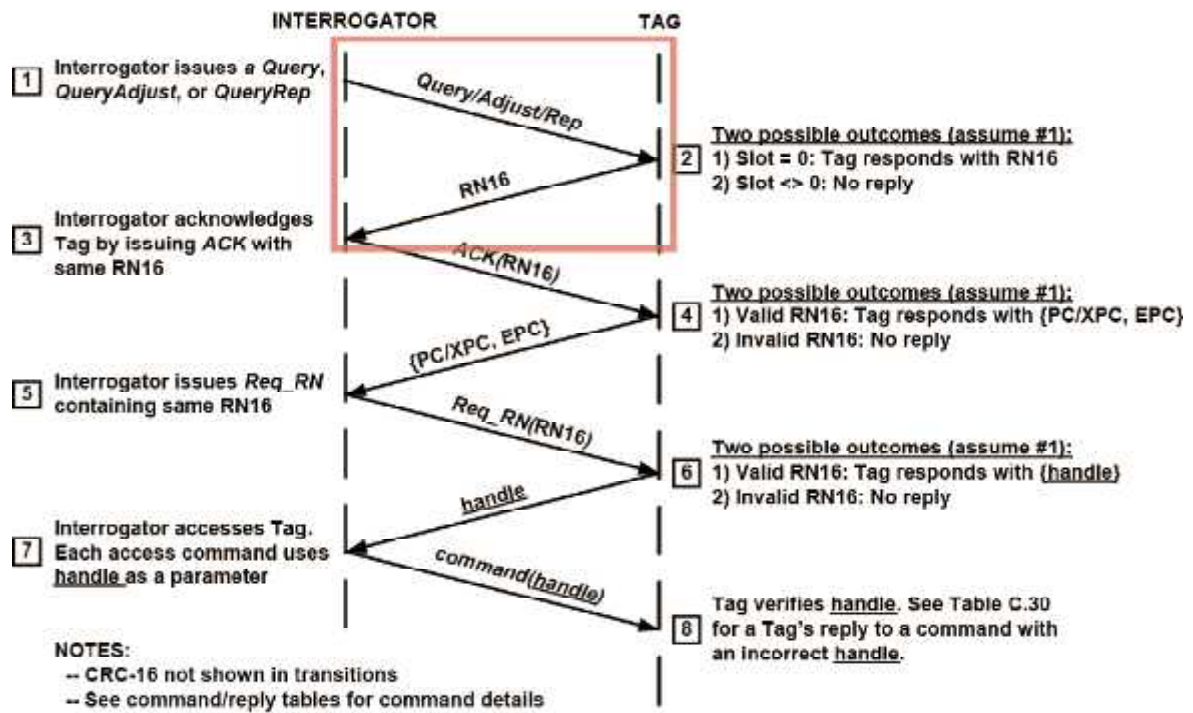
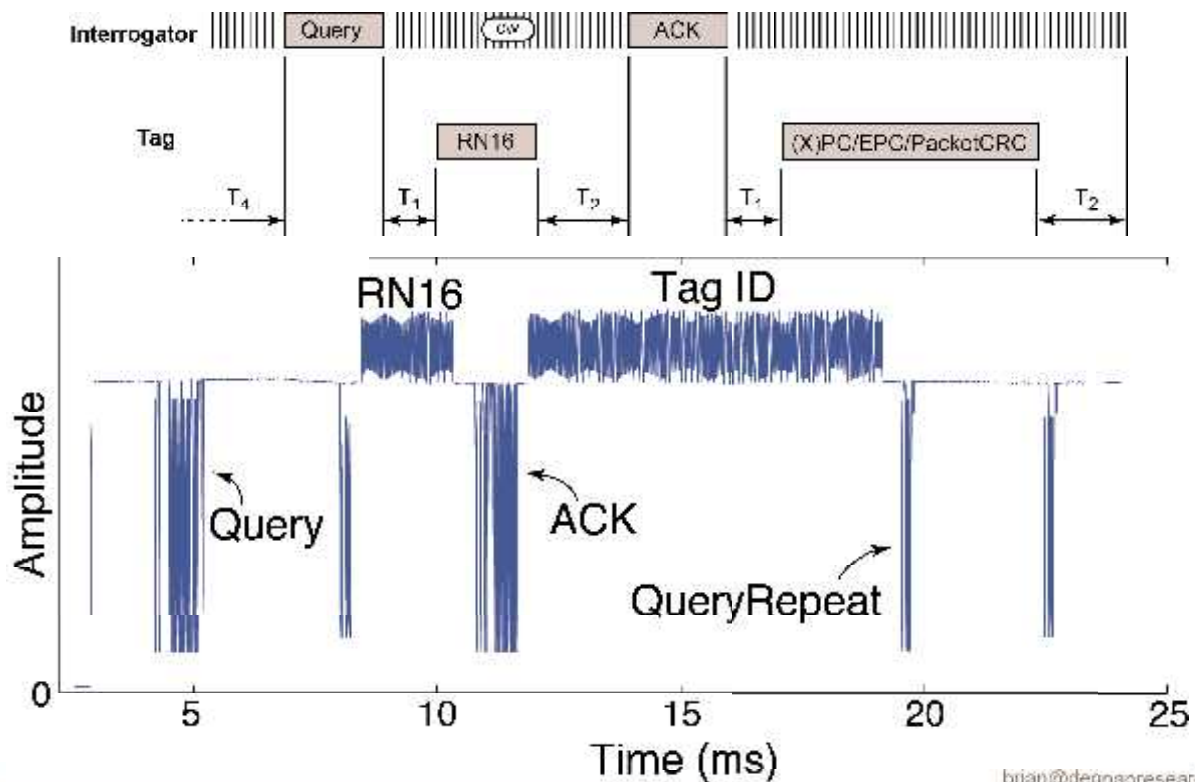
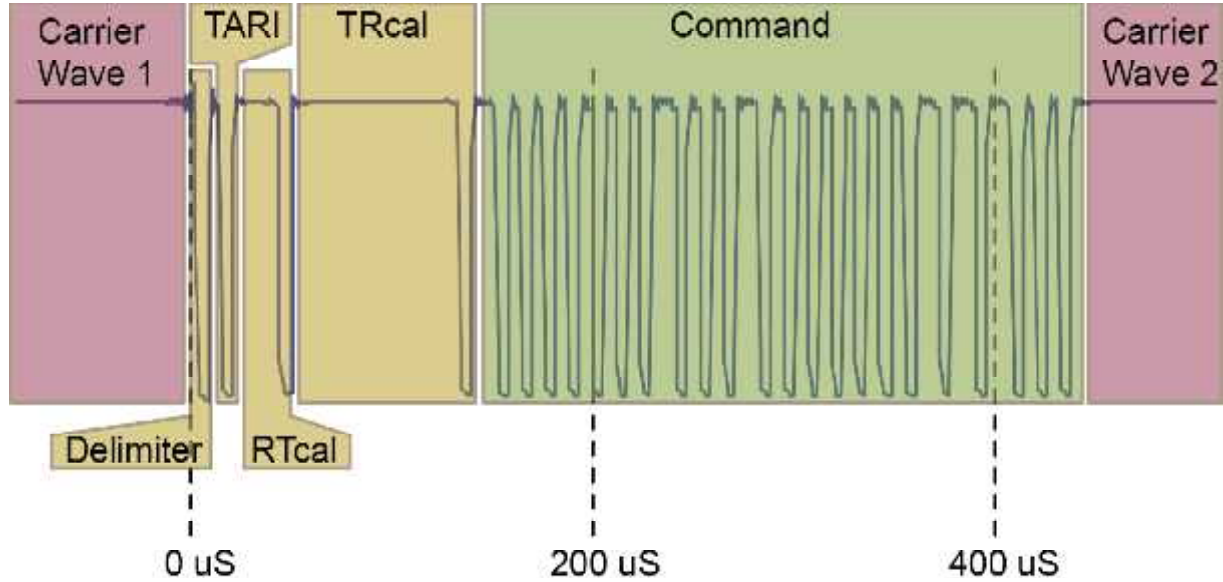


Figure E.1: Example of Tag inventory and access

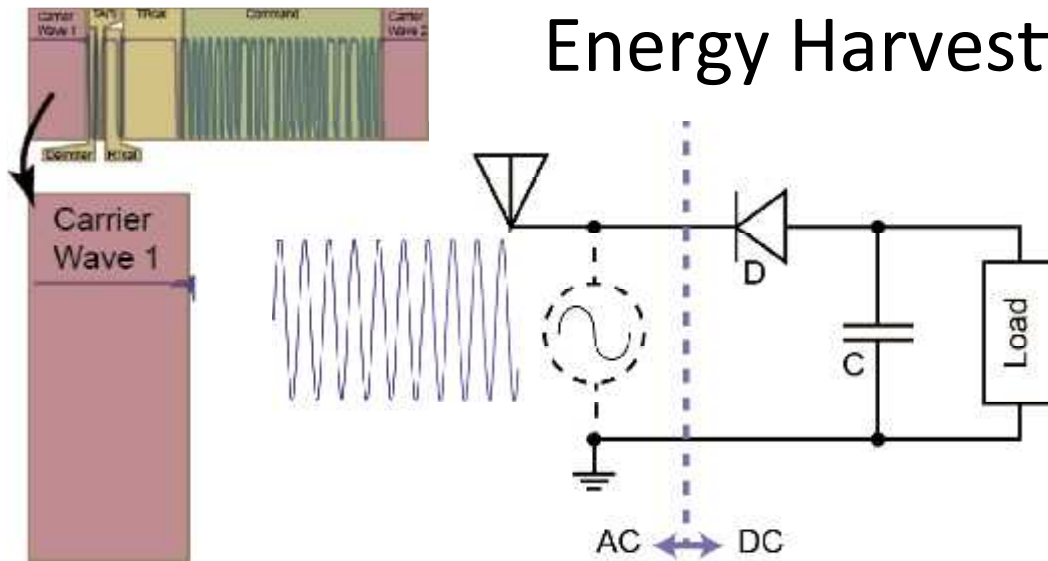
Commands in Context



Gen2 Waveform and Vocabulary

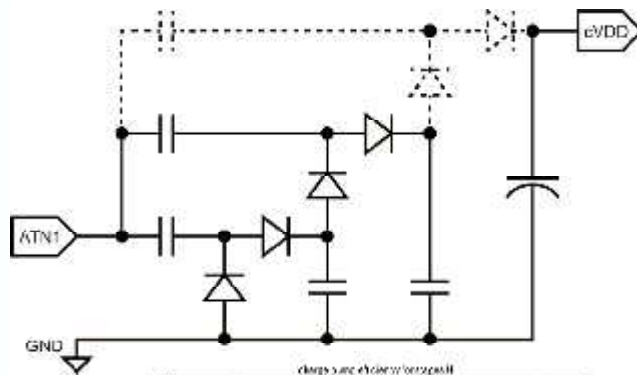


Energy Harvesting



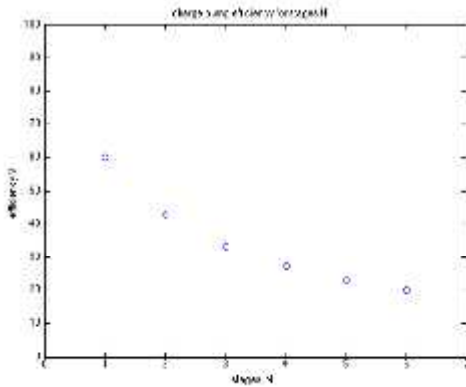
Node (nm)	V_{DD}	I_{sat} (μA)	V_{thn}	Sub-Vt%	I_{DS0} (pA)	ITRS target I_{DS0} (pA)
130	1.2	55.5	0.4	33.3	167.1	130
90	1.0	44.4	0.38	38.0	960.3	900
65	1.0	48.5	0.4	40.0	8138.7	6500

Energy Harvesting

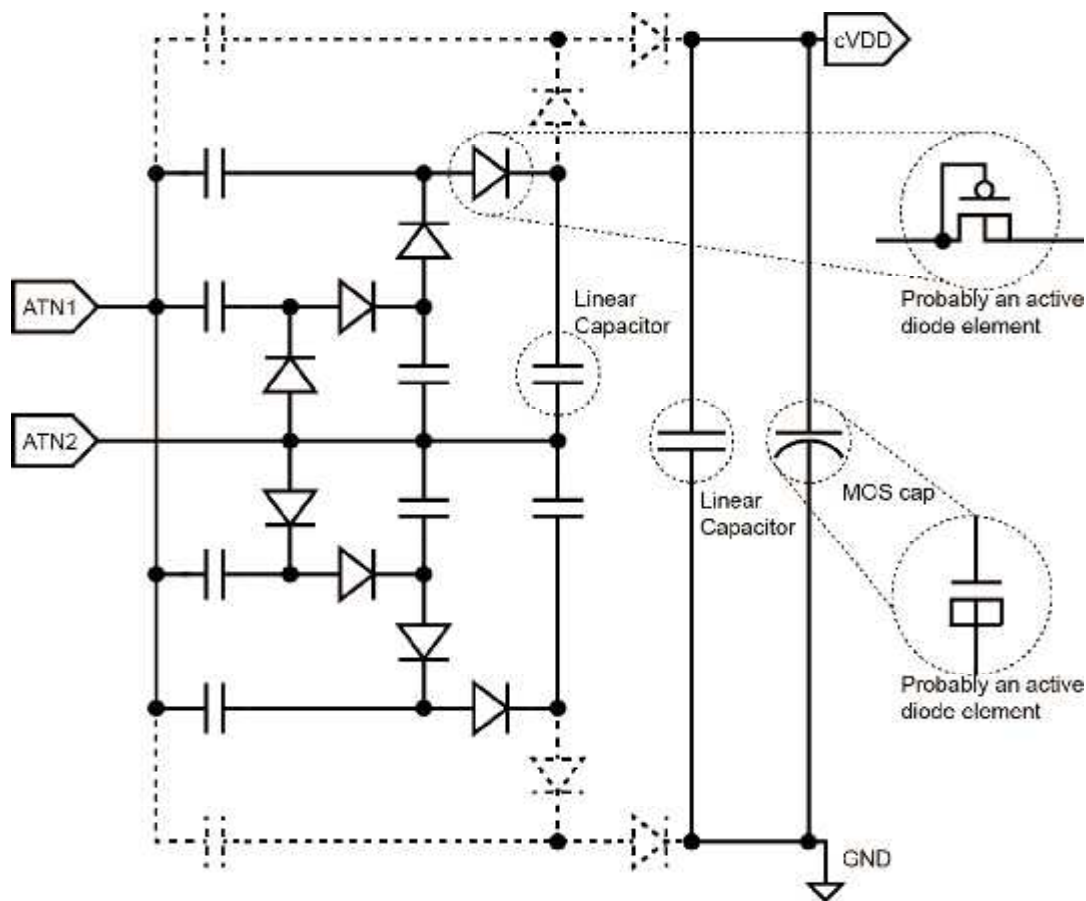


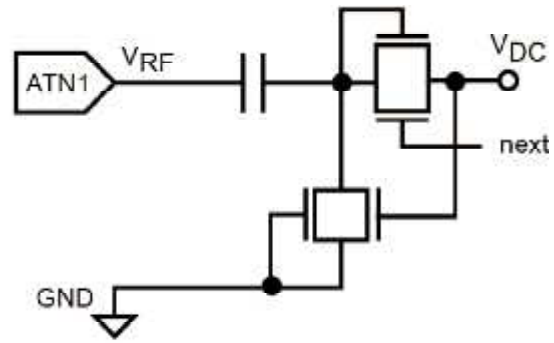
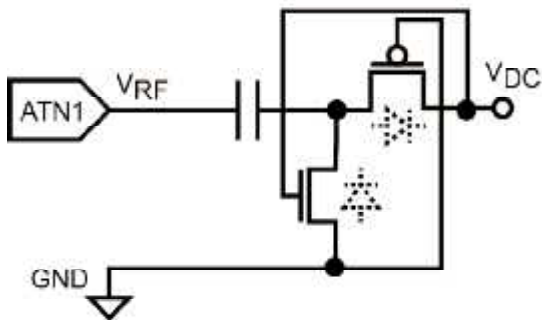
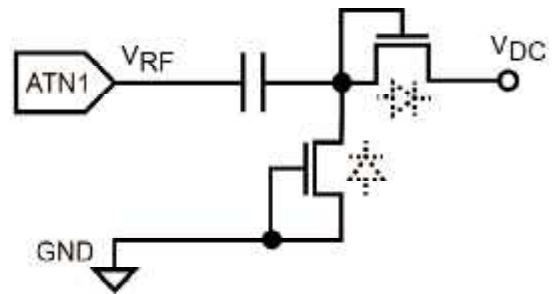
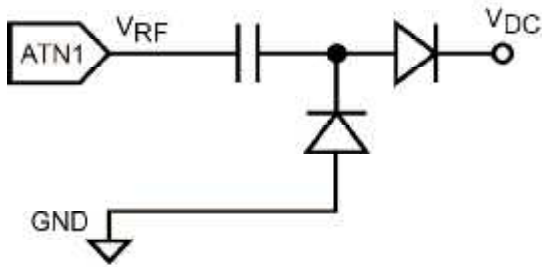
$$V_{DDid} = 2N (V_p - V_{on})$$

$$\eta_{cp} = \frac{V_{DD}}{V_{DD} + 2NV_{on}}$$



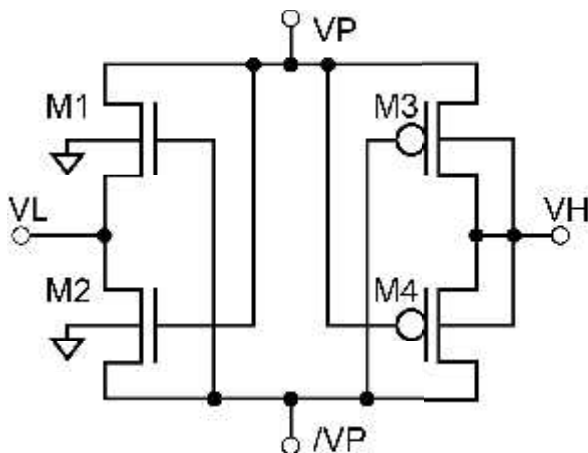
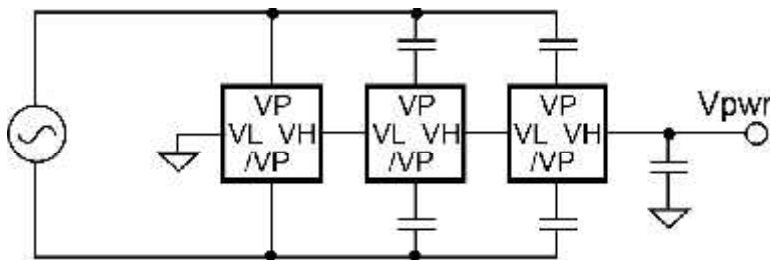
- Number of stages
- Received Energy
- Current Load
- Et Cetera



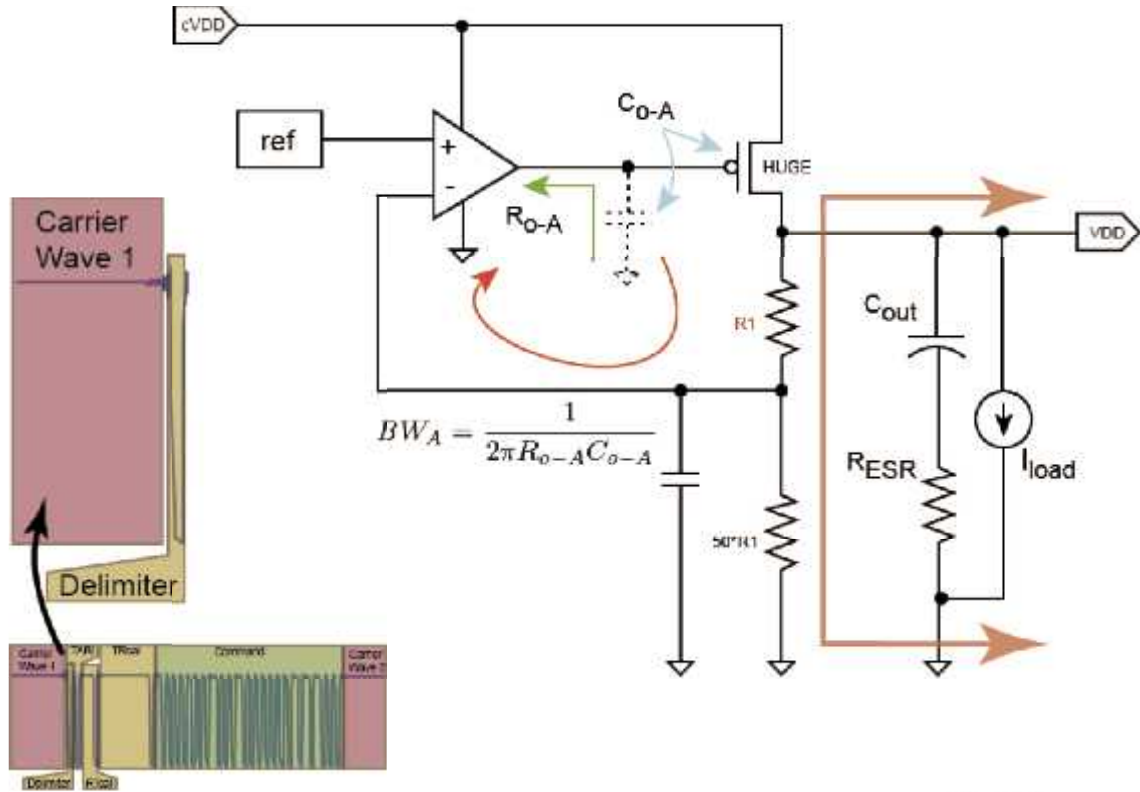


Wu et al, "MOS Charge Pumps for Low-Voltage Operation" JSSC 1998

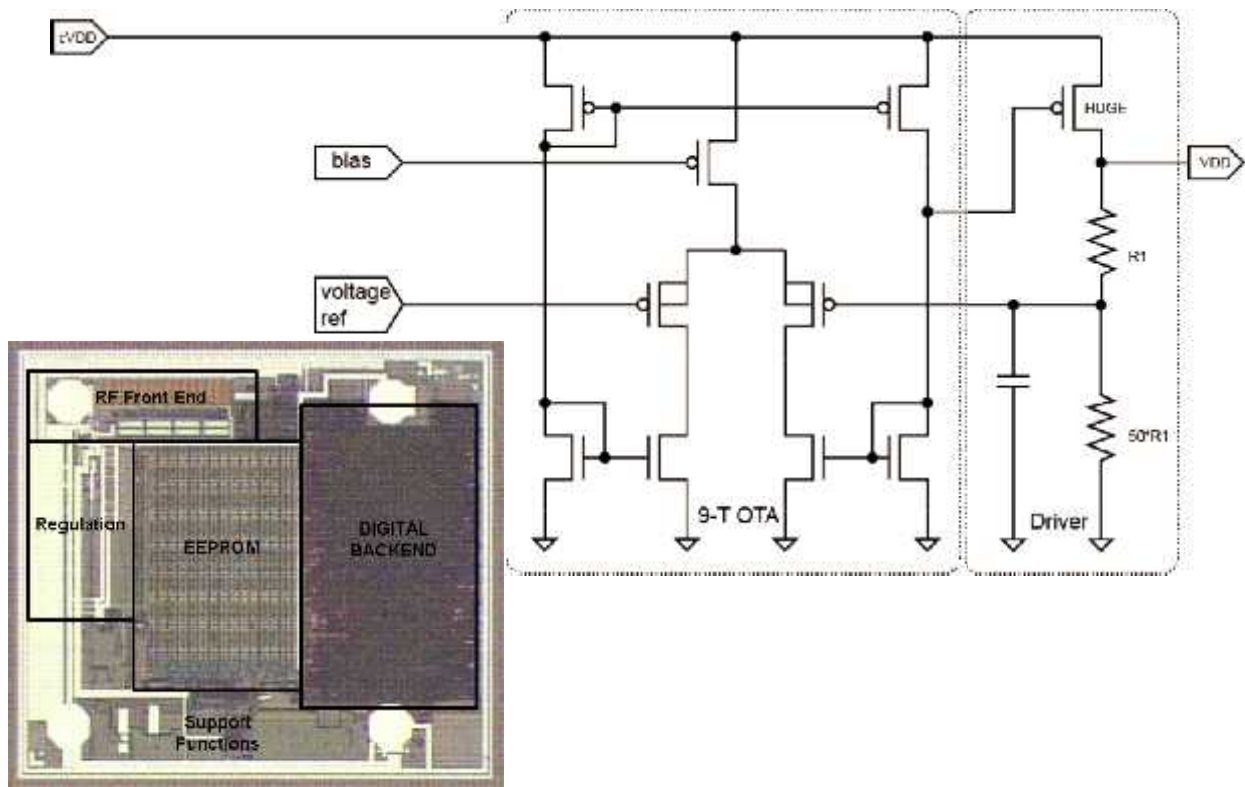
CMOS H-Bridge Charge Pump



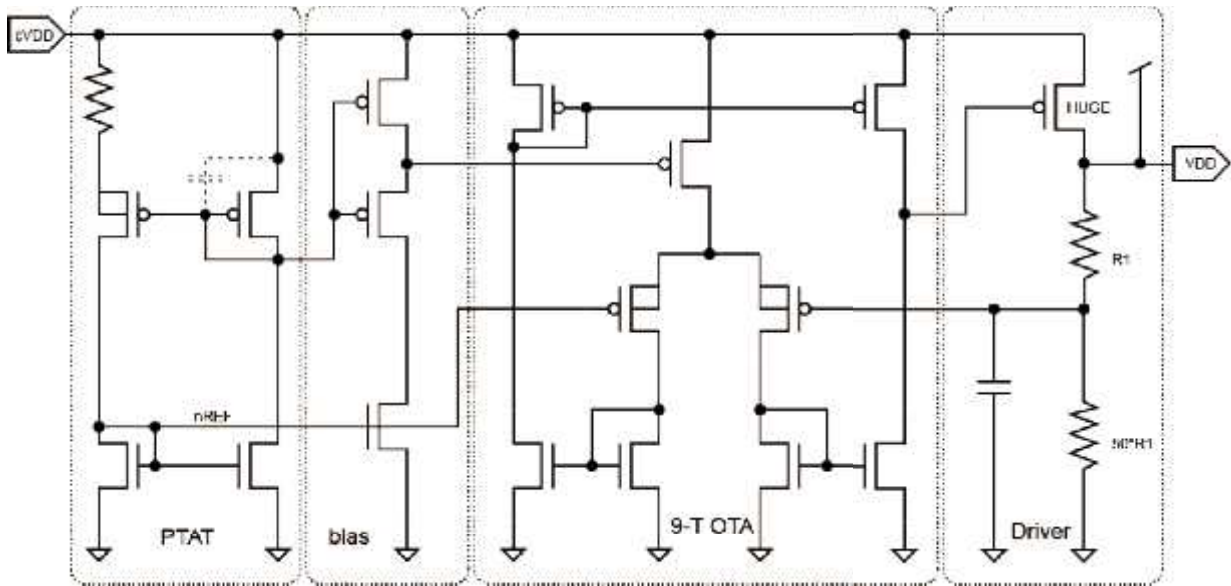
Power Regulator



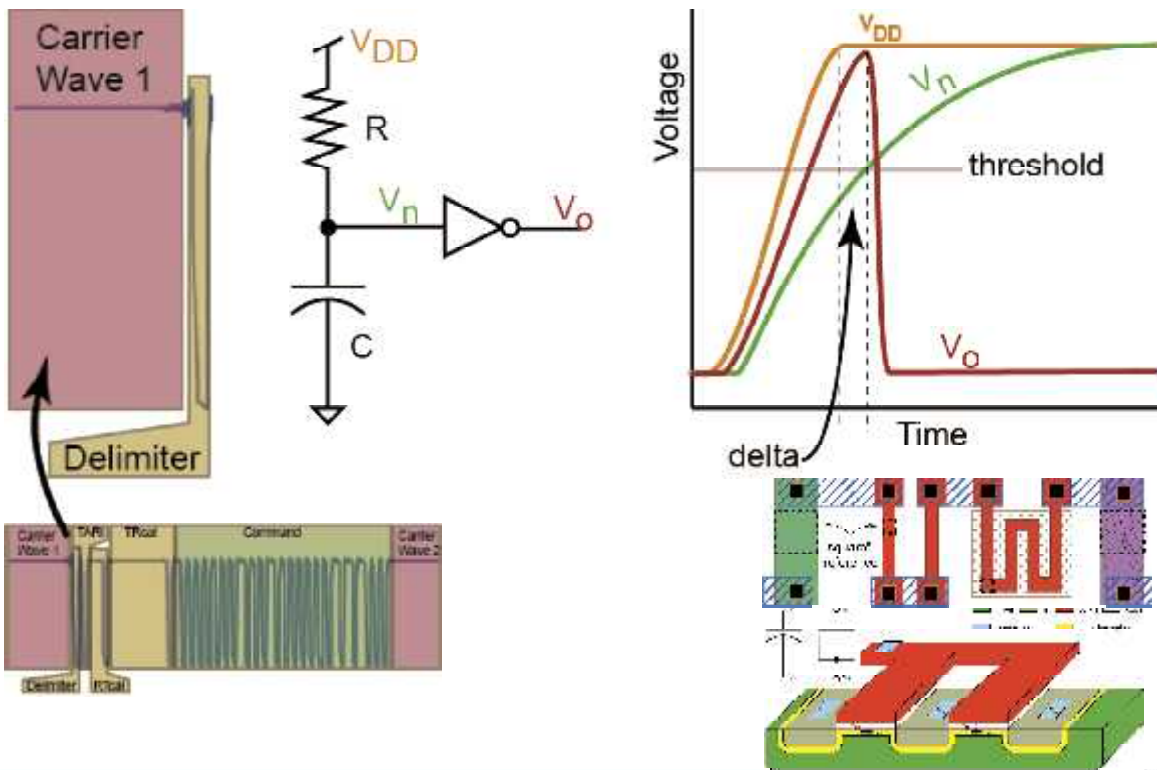
Amplifier and "load"



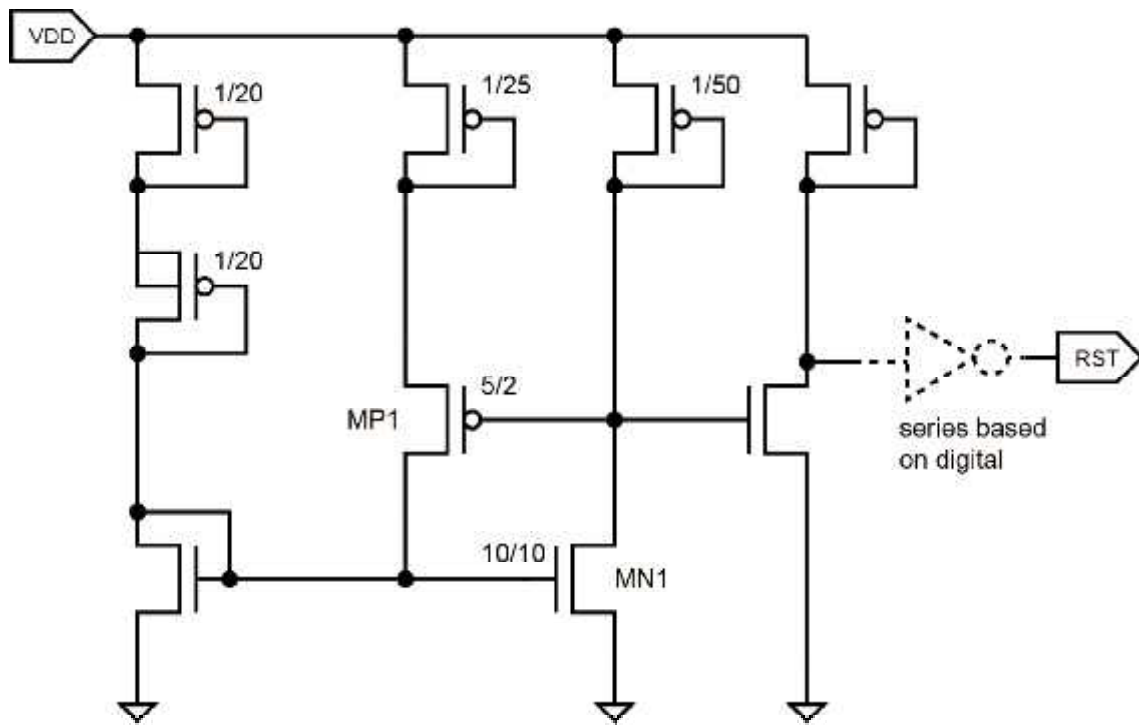
Power Regulator Complete



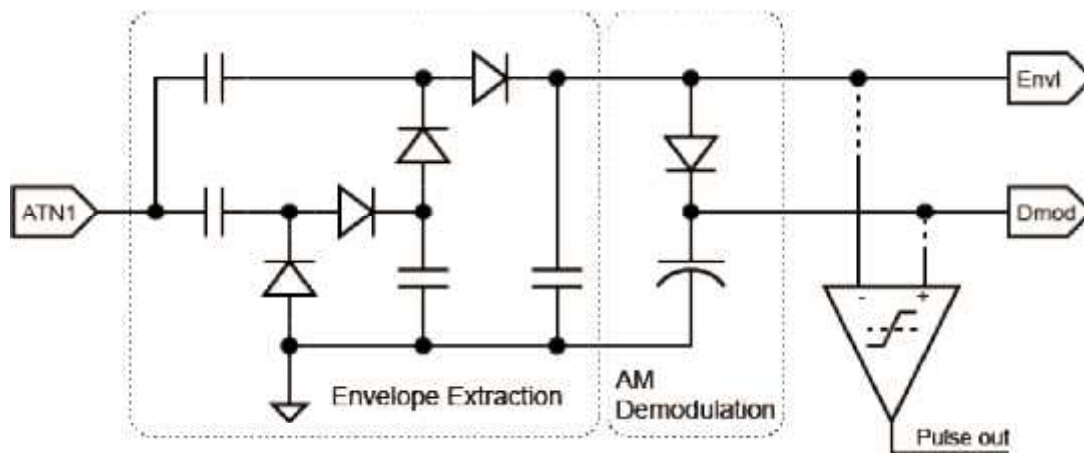
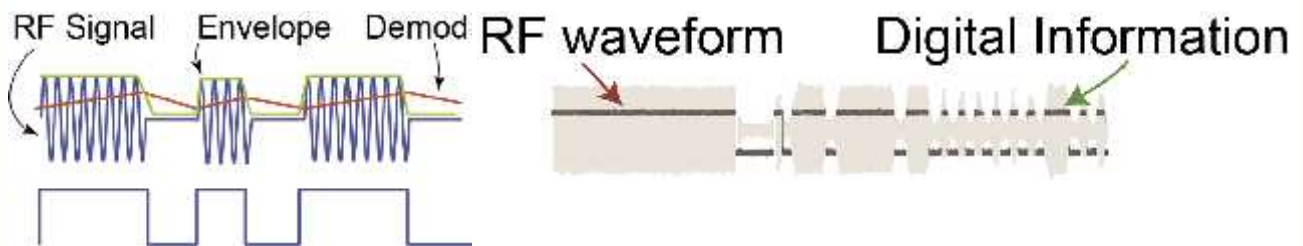
Digital POR



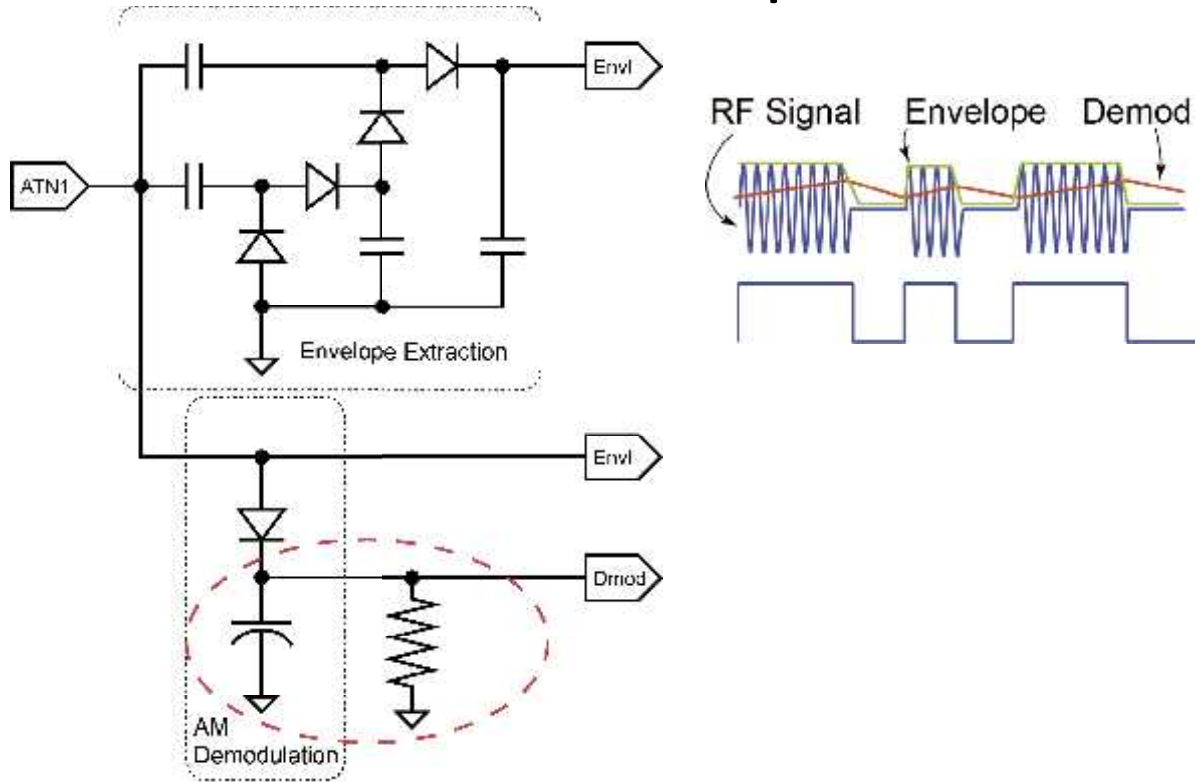
Power-On-Reset



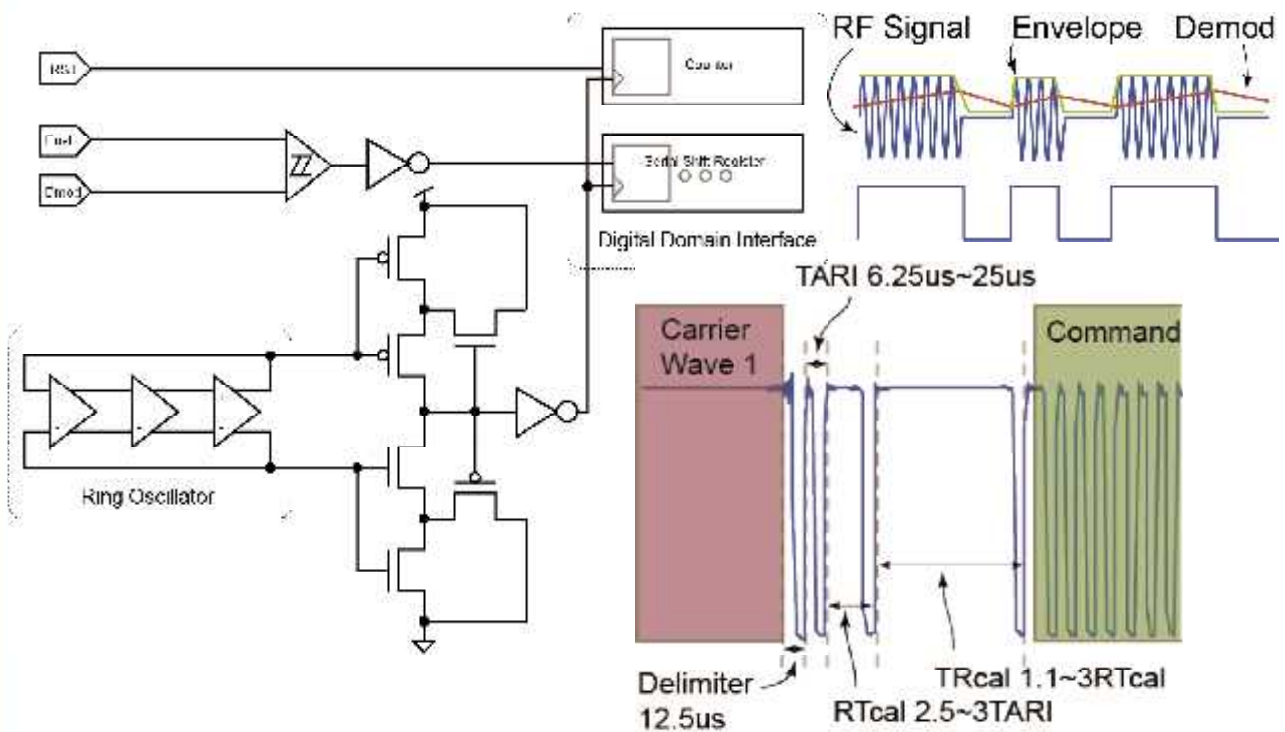
Demodulation

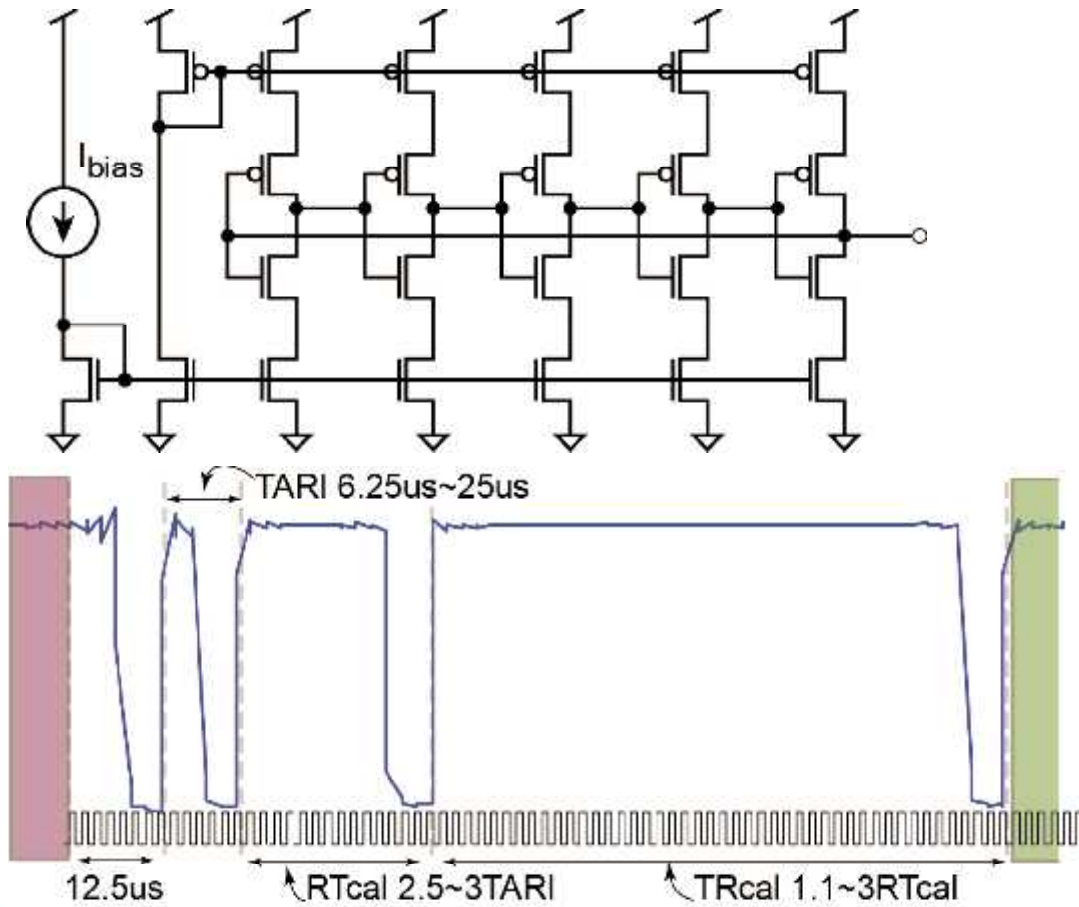


Demodulation pitfalls

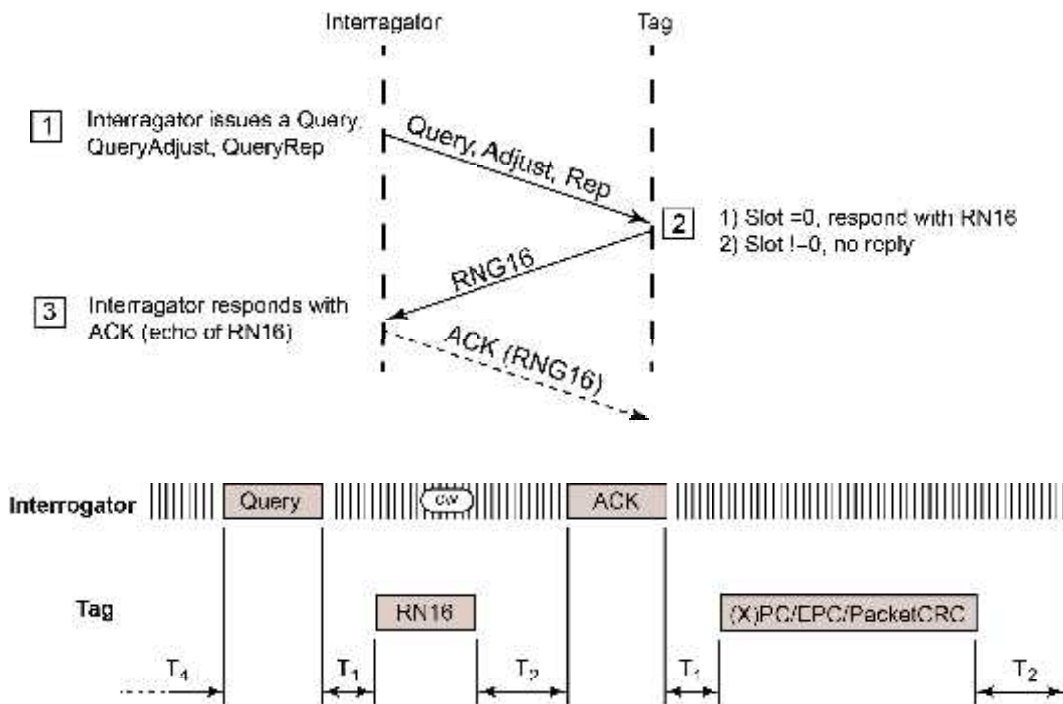


Data Extraction

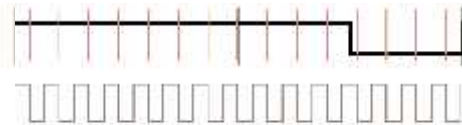
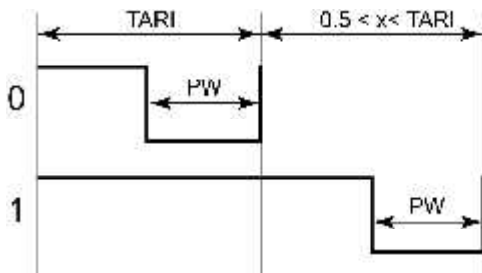
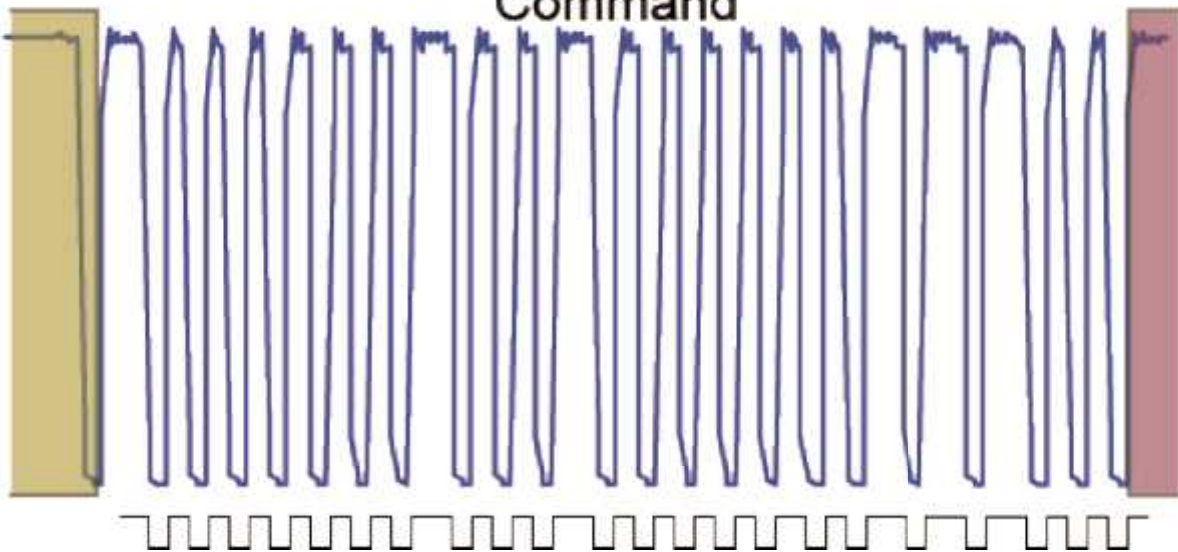




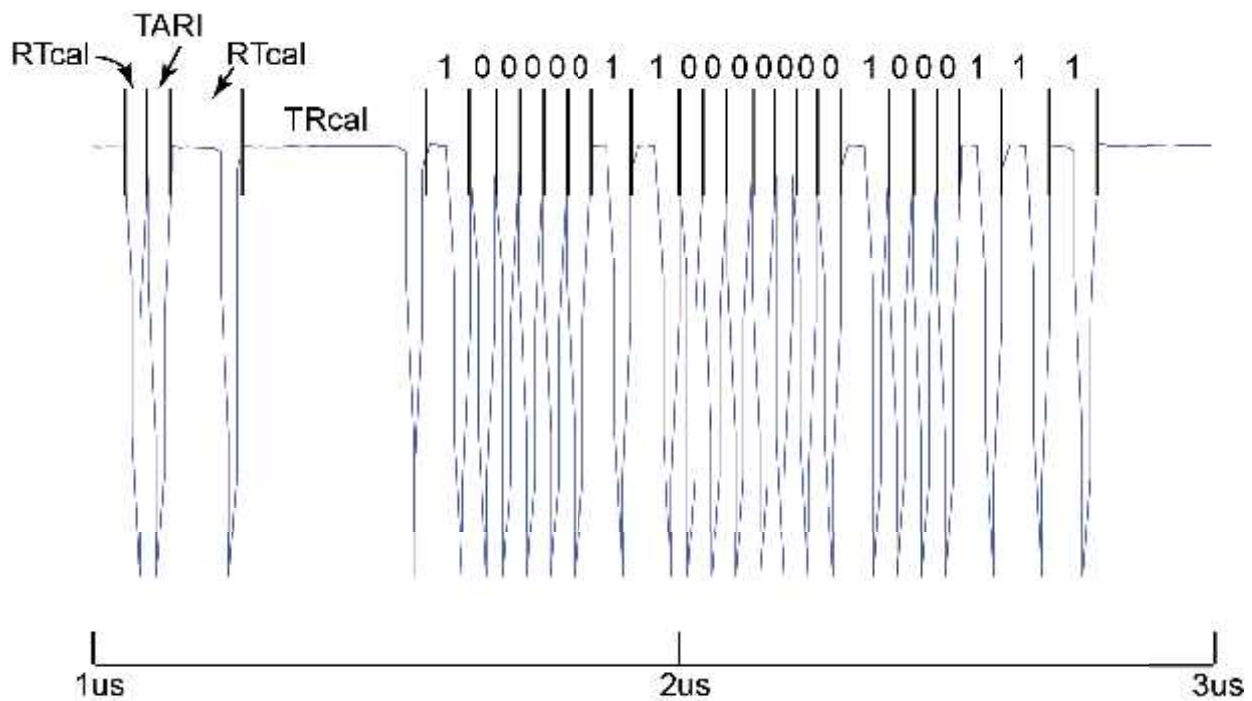
Gen2 State Machine



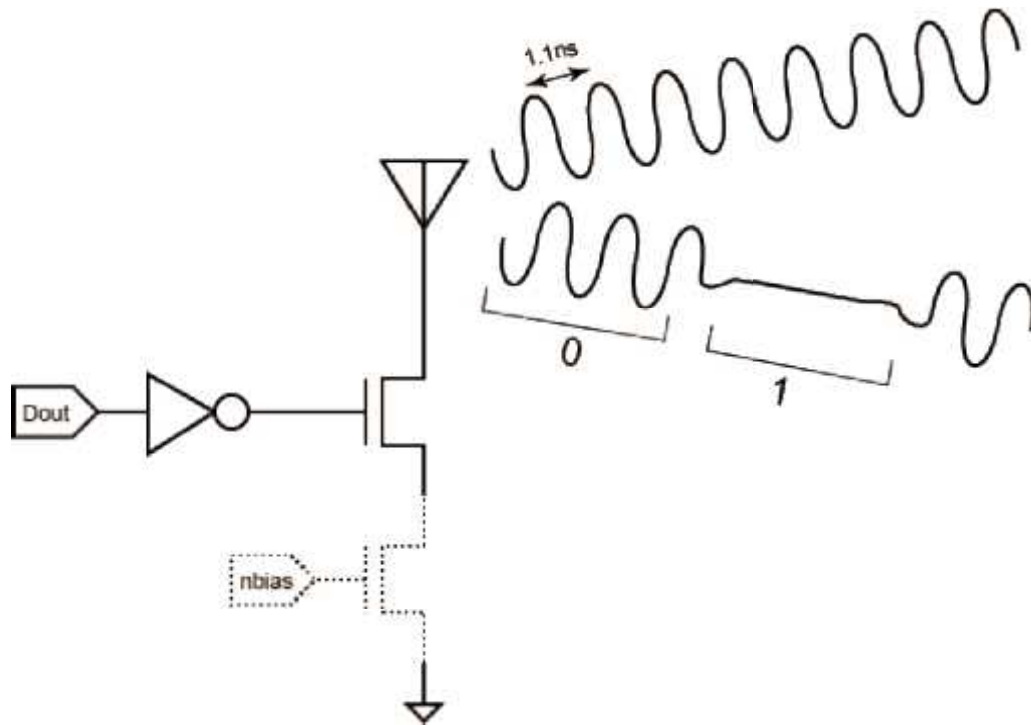
Command



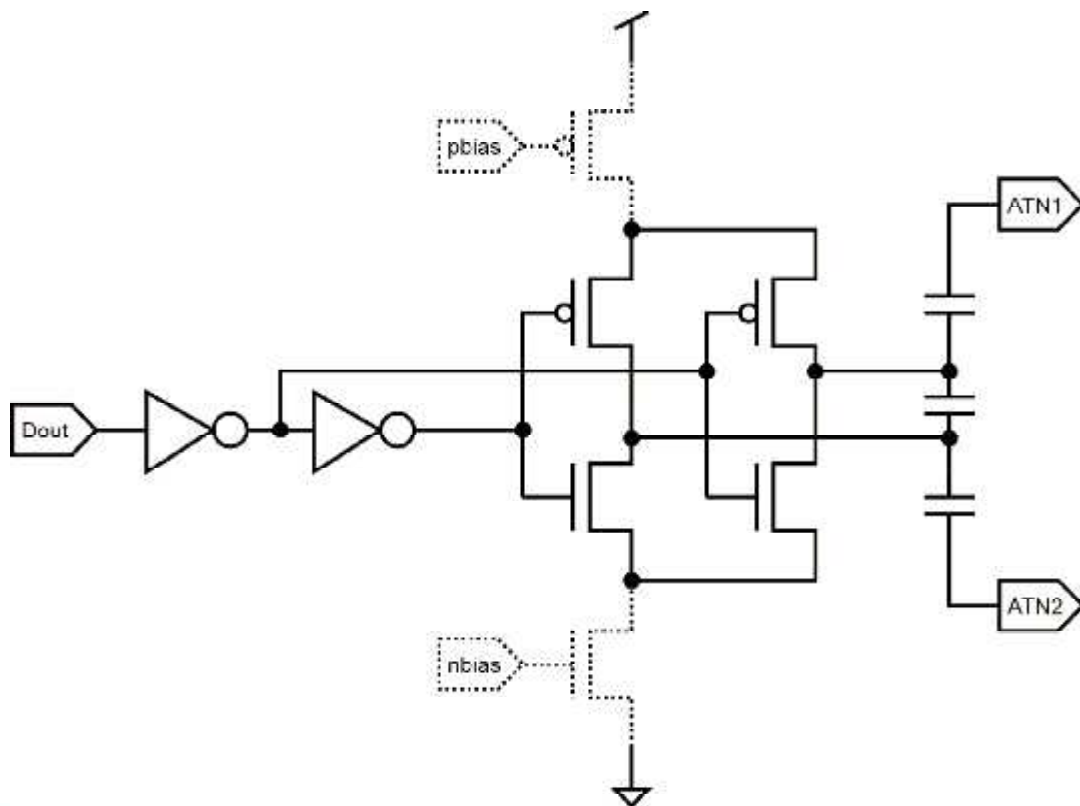
QUERY command



Conceptual Modulated Response



Modulated Response Circuit



Gen2 Protocol, again

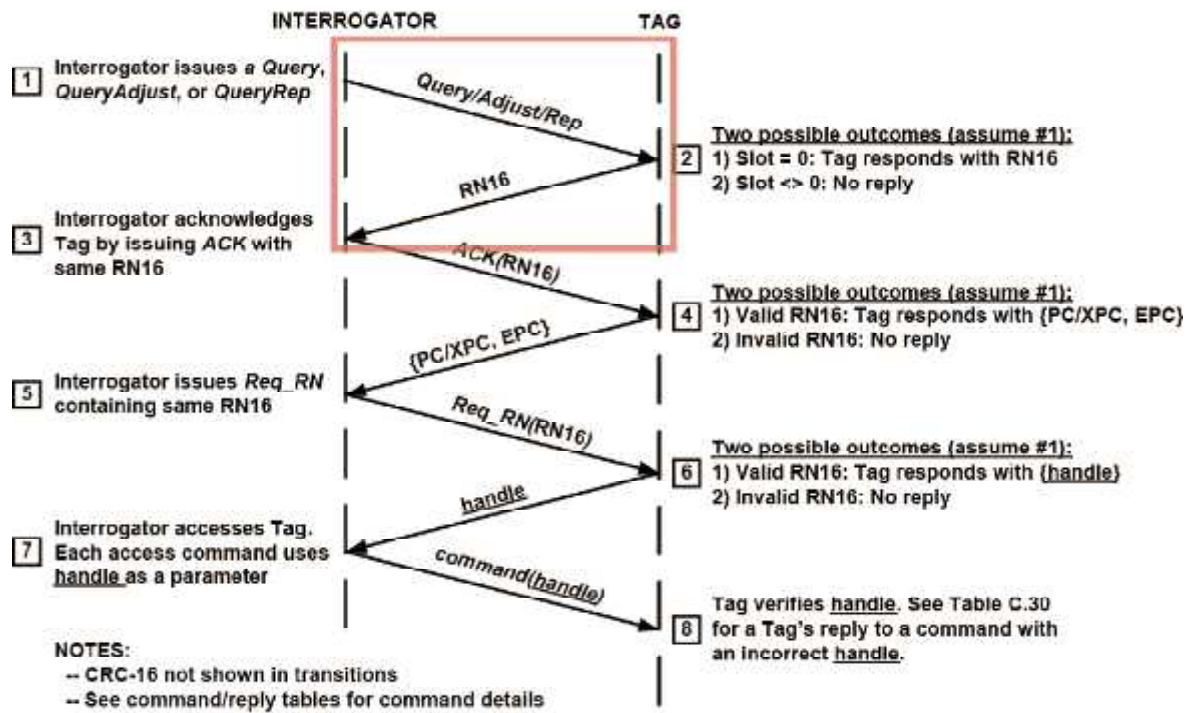
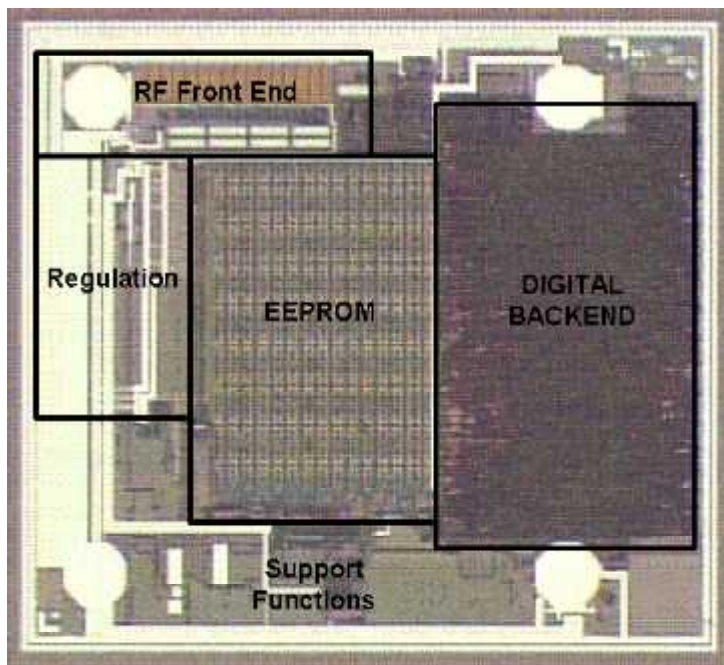


Figure E.1: Example of Tag inventory and access

brian@degnanresearch.com

Example Tag



0.5mm² Tag:

Digital ~ 30%

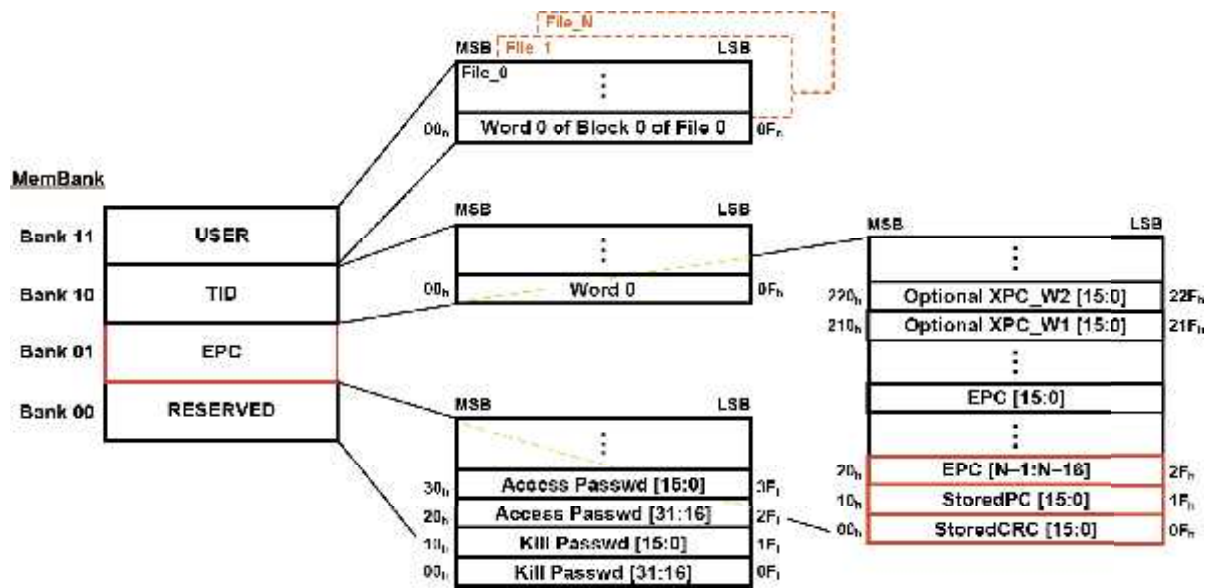
EEPROM ~ 20%

RF + DC reg ~ 20%

Others (RNG, Charge Pump, support functions): 30%

brian@degnanresearch.com

Tag Memory: What is stored?



EPC Memory

EPC Word Address	EPC word Contents	EPC Word Values			
0x00	StoredCRC	0xE2F0	0xCCAE	0x968F	0x78F6
0x10	StoredPC	0x0x0000	0x0800	0x1000	0x1800
0x20	EPC word 1	N/A	0x01111	0x1111	0x1111
0x30	EPC word 2	N/A	N/A	0x2222	0x2222
0x40	EPC word 3	N/A	N/A	N/A	0x3333

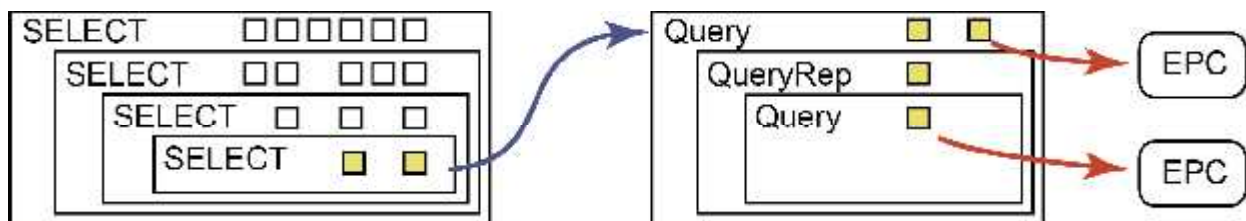
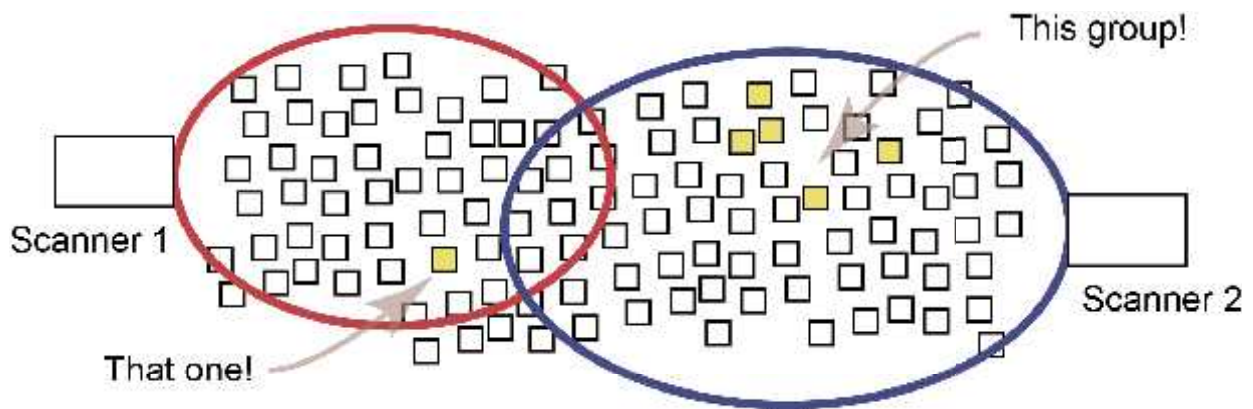
dec	bin	polynomial
0	000	0
1	001	1
2	010	x
3	011	$x + 1$
4	100	x^2
5	101	$x^2 + 1$
6	110	$x^2 + x$
7	111	$x^2 + x + 1$

$$x^{16} + x^{12} + x^5 + 1$$

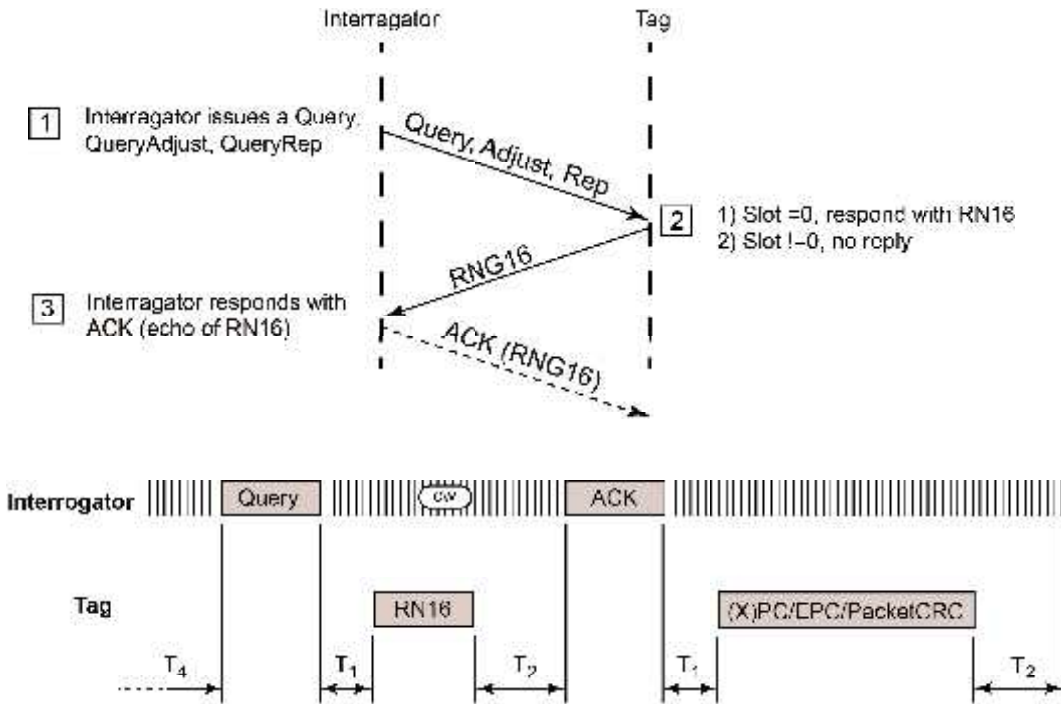
Mandatory Commands

Command	Code	Bits	Description
ACK	01	18	Tag sends RN16 or Handle
Kill	11000100	59	Permanently disable tag
Lock	11000101	60	Prevents memory overwrites
NAK	11000000	8	Keep state bits
Query	1000	22	Send back information
QueryAdjust	1001	9	Changes Slot total
QueryRep	00	4	Decrement Slot Counter
Read	11000010	>57	Read word from memory
Rcq RN	11000001	40	Tag sends new RN16
Select	1010	>44	Select groups of tags
Write	11000011	>58	Write word to memory

Tags! Management of chaos

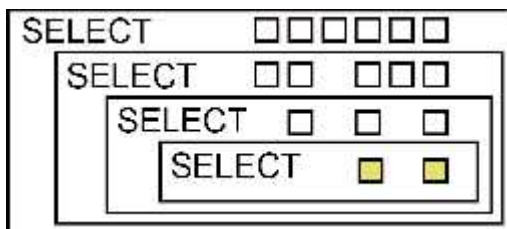
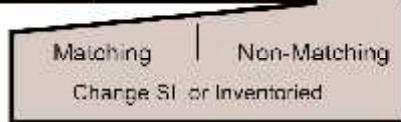


Gen2 State machine, getting the EPC.

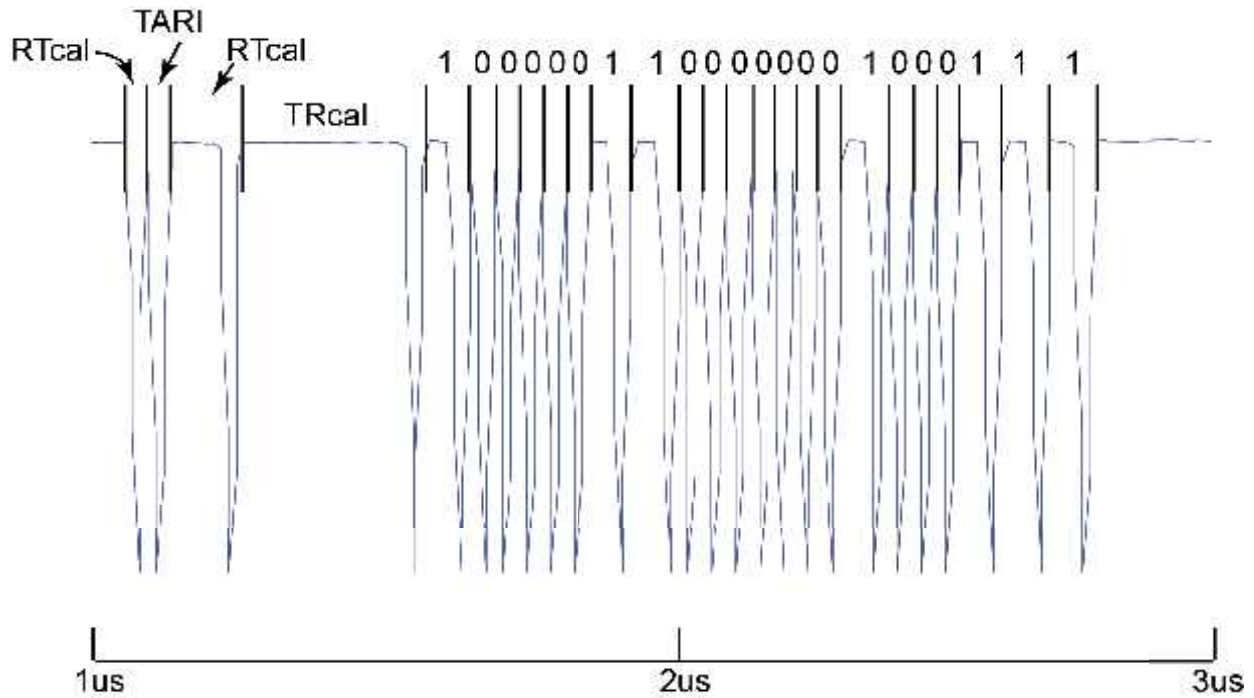


Select

	Command	Target	Action	MemBank	Pointer	Length	Mask	Truncate	CRC
# of bits	4	3	3	2	EBV	8	Variable	1	16
description	1010	000: Inventoried (S0) 001: Inventoried (S1) 010: Inventoried (S2) 011: Inventoried (S3) 100: SL 101: RFU 110: RFU 111: RFU		00: FileType 01: EPC 10: TID 11: File_0	Starting Mask address	Mask length (bits)	Mask value	0: Disable truncation 1: Enable truncation	CRC 16

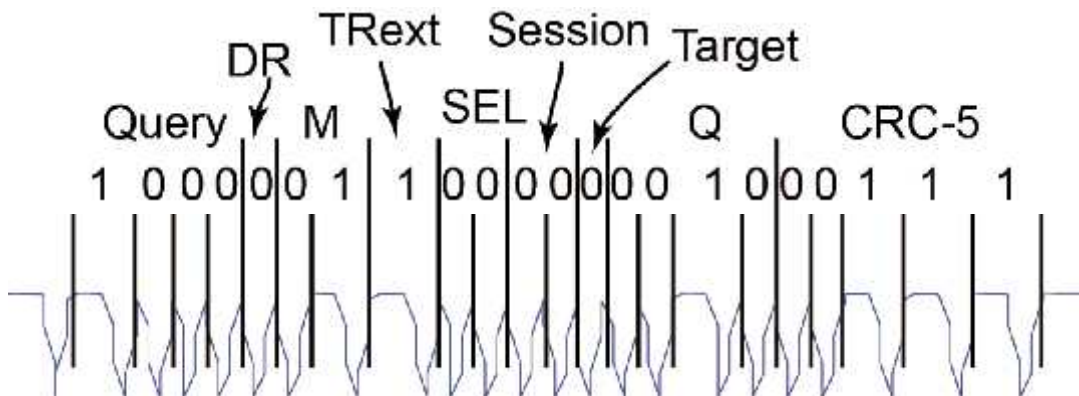


QUERY command

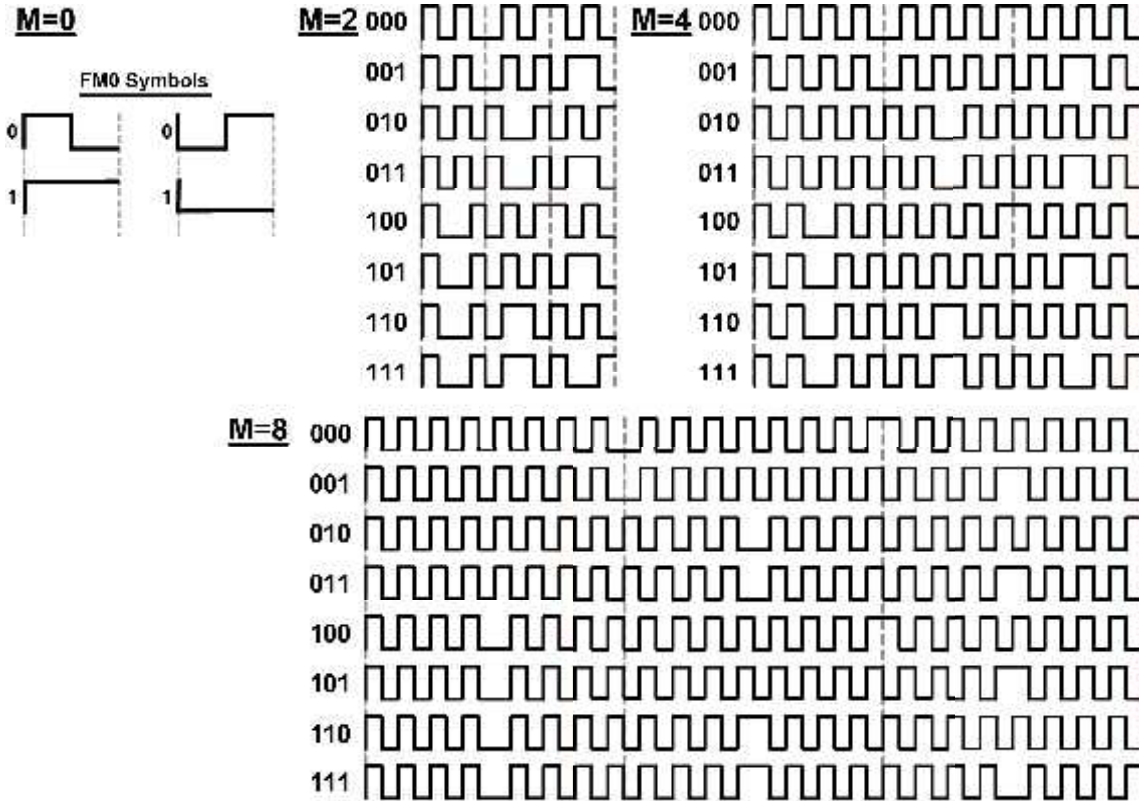


Query Bits

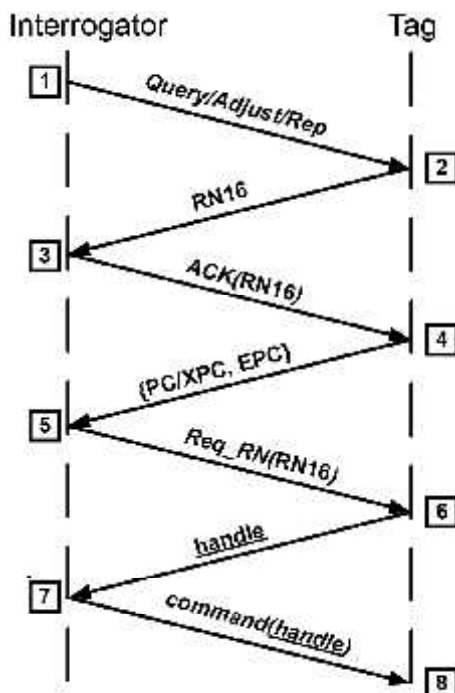
	Command	DR	M	TRext	SEL	Session	Target	Q	CRC
# of bits	4	1	2	1	2	2	1	1	5
description	1000	0: DR=8 1: DR=64/3	00: M=1 01: M=2 10: M=4 11: M=8	0: No pilot tone 1: Use pilot tone	00: All 01: All 10: ~SL 11: SL	00: S0 01: S1 10: S2 11: S3	0: A 1: B	0-15	CRC-5



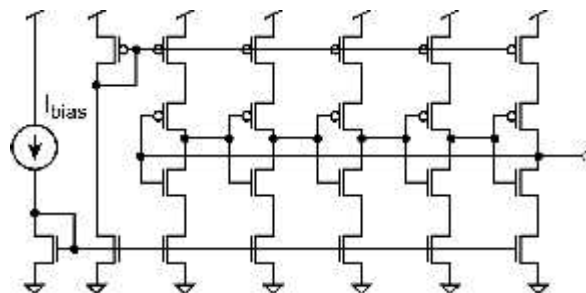
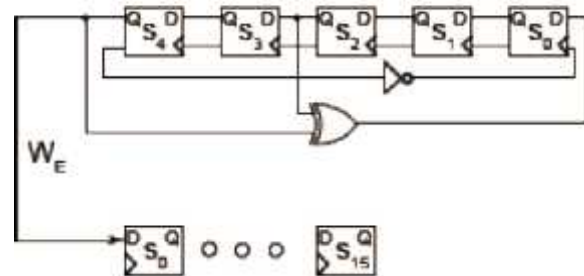
Talking Back, the "M" bit



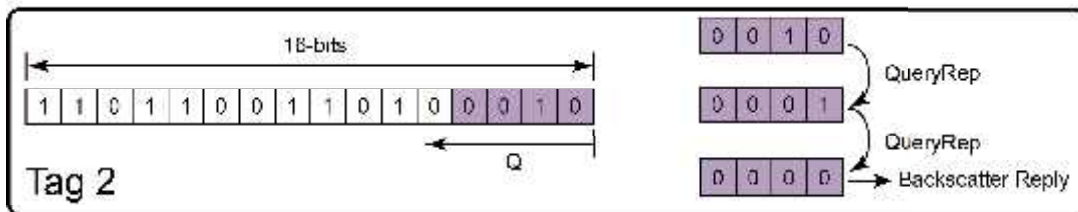
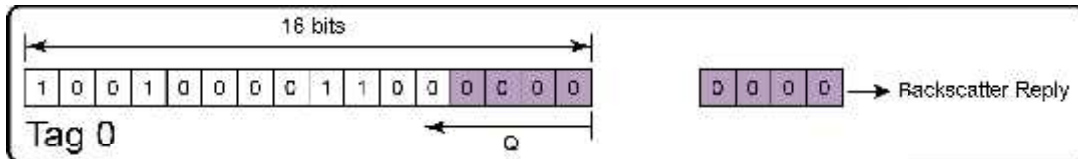
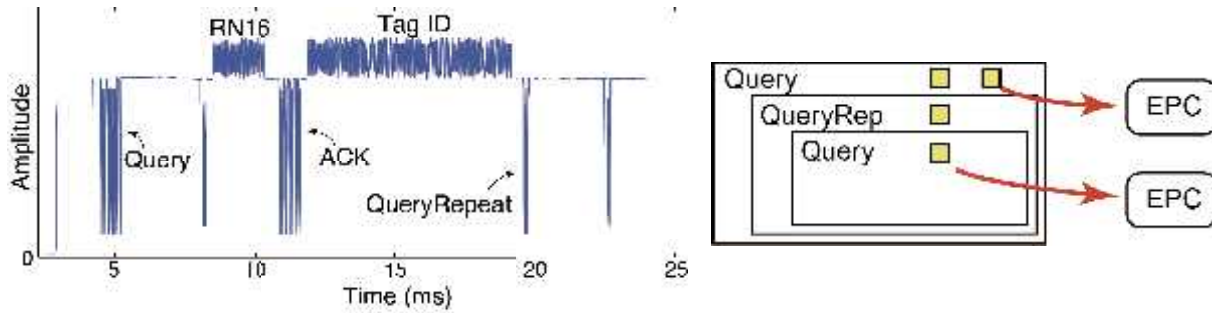
RN16 for response and slot counter



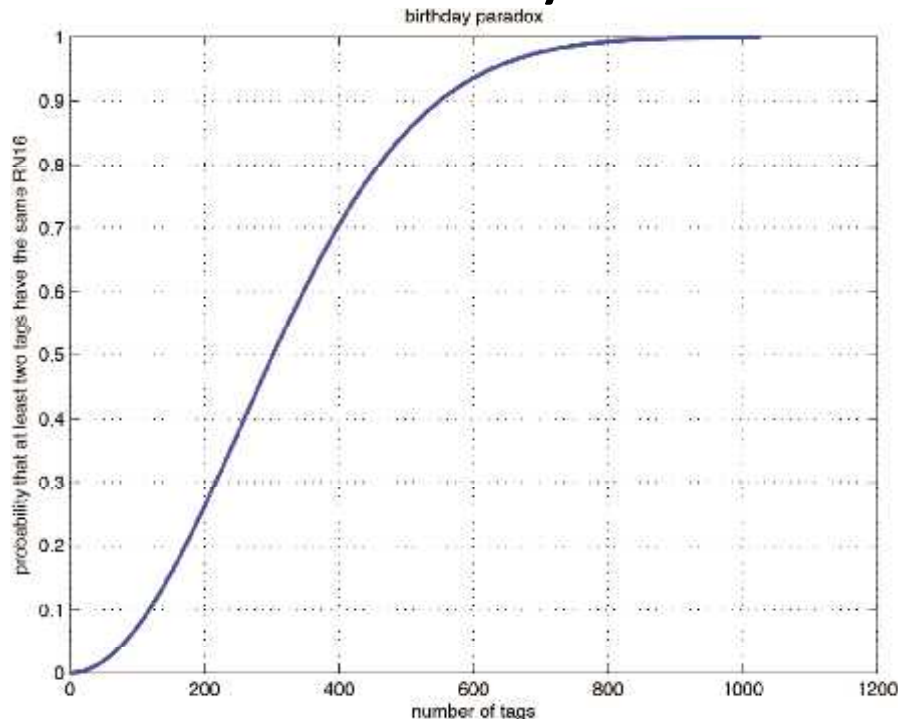
$$W_E = 10000100101100111110001101110101$$



Slot Counter, QueryRep



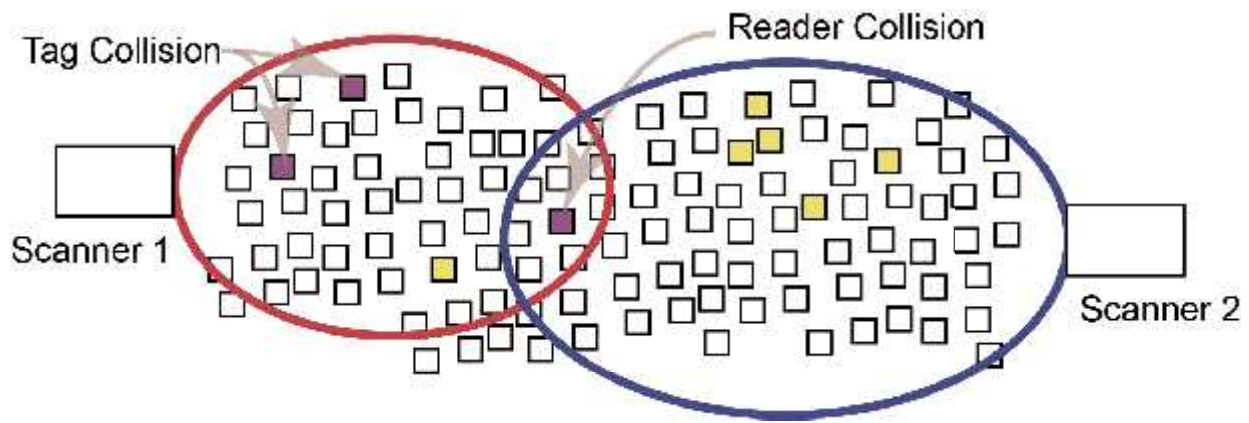
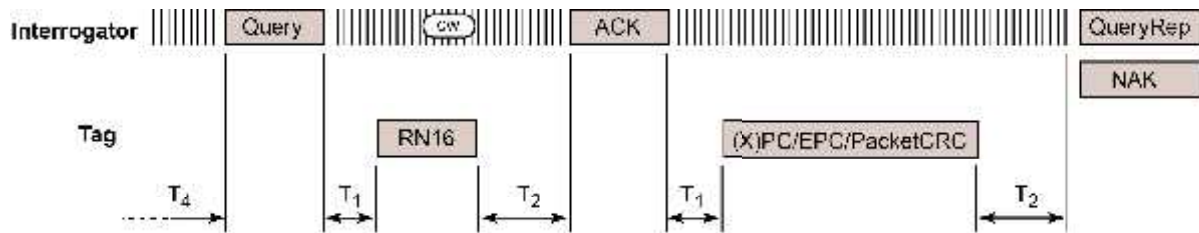
RN16: Birthday Paradox



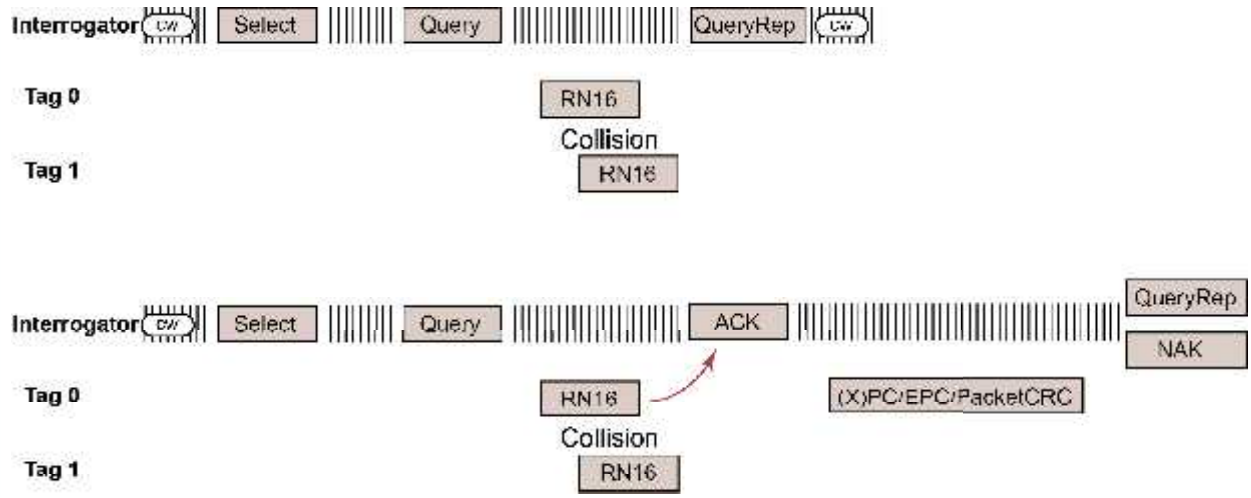
$$p = 1 - e^{-\frac{k^2}{2N}}$$

$$p = 1 - e^{-\frac{k^2}{2(2^{16})}}$$

Collisions, but first: a good packet



Packet Collision and Recovery



Introduction to Cryptography

- Asymmetric
- Public/private key
- Send over insecure channel
- Bit widths ~1000s
- Relatively Slow
- Symmetric
- Private Key
- Uses Asymmetric crypto to send key
- Bit widths 64~256
- Quite Fast

Cryptography in Gen2V2

- Gen2v2 has NONE (by design)
- User's choice of underlying cryptography
- Defines the commands and responses

Command	Code	Description
Authenticate	11010101	Authenticate against Challenge
AuthComm	11010111	Encapsulate command securely
Challenge	11010100	Crypto "Select" command
KeyUpdate	11000101	Update an encryption key
SecureComm	11010110	Encapsulate command securely
TagPrivilege	1110001000000011	Set tag access
Untraceable	1110001000000000	Hide from other interrogators

ISO/IEC 29167

29167-10	AES-128	Published (revision in progress)
29167-11	PRESENT-80	Published
29167-12	ECDH	Published
29167-13	Grain-128a	Published
29167-14	AES-128	Published
29167-15	XOR	Halted
29167-16	ECDSA	Published
29167-17	CryptoGPS	Published
29167-18	Hummingbird v2	Withdrawn
29167-19	RAMON	Published
29167-20	Algebraic Eraser	Working draft
29167-21	Simon	Working draft
29167-22	Speck	Working draft

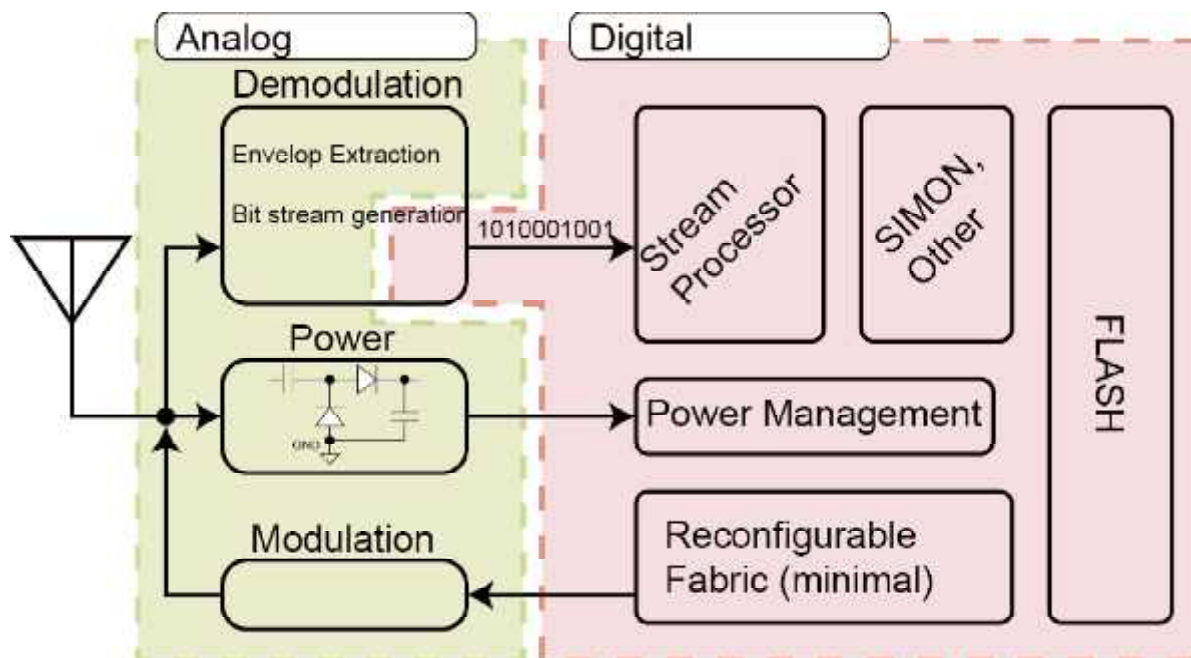
The crypto problem?

- Passive RFID is a long read range, but is very power constrained
- Different use-cases prioritize different performance attributes
- Different use-cases have different security/threat models
- Deployment is complex
- Symmetric ciphers: lowest complexity

Cryptography on RFID

- No device authentication
- 128-bit keys with poor side-channel profiles vs 80-bit keys with good side-channel profiles vs “it’s a \$10 t-shirt”
- Tags often only used a few times
- Cryptography is used to authenticate the tag, not protect the data.

RFID tag of the future



Example of Key Exchange

Me	You
<i>Prime, $P = 29, \alpha = 2$</i>	
$secret_{me} = 5$ $\alpha^{secret_{me}} = 2^5 = 32$ $= x \pmod{P}$ $= 3 \pmod{29}$	$secret_{you} = 12$ $\alpha^{secret_{you}} = 2^{12} = 4096$ $= y \pmod{P}$ $= 7 \pmod{29}$
$y^{secret_{me}} = Z \pmod{P}$ $7^5 = Z \pmod{29}$	$x^{secret_{you}} = Z \pmod{P}$ $3^{12} = Z \pmod{29}$
$Z = 16$	

Questions?



